° ICOM

SERVICE MANUAL

144MHz FM TRANSCEIVER IC-2100H IC-2100-T

Icom Inc.

INTRODUCTION

This service manual describes the latest service information for the **IC-2100H/IC-2100-T** 144 MHz FM TRANSCEIVER at the time of publication.

MODEL	VERSION	SYMBOL
	Europe	EUR
	Italy	ITA
	Taiwan	TPE
IC-2100H	U.S.A	USA
	Asia	SEA
	Latin America	LA
IC-2100-T	Thailand	THA

To upgrade qualty, any electrical or mechanical parts and internal circuits are subject to chang without notice or obligation

DANGER

NEVER connect the transceiver to an AC outlet or to a DC power supply that uses more than 16 V. This will ruin the transceiver.

DO NOT expose the transceiver to rain, snow or any liquids.

DO NOT reverse the polarities of the power supply when connecting the transceiver.

DO NOT apply an RF signal of more than 20 dBm (100mW) to the antenna connector. This could damage the transceiver's front end.



ORDERING PARTS

Be sure to include the following four points when ordering replacement parts:

- 1. 10-digit order numbers
- 2. Component part number and name
- 3. Equipment model name and unit name
- 4. Quantity required

<SAMPLE ORDER>

1110002550 IC TA725AP IC-2100H MAIN UNIT 5 pieces 8810008660 Screw PH BO M3x8 NI IC-2100H Chassis 10 pieces

Addresses are provided on the inside back cover for your convenience.

REPAIR NOTES

- Make sure a problem is internal before disassembling the transceiver.
- DO NOT open the transceiver until the transceiver is disconnected from its power source.
- DO NOT force any of the variable components. Turn them slowly and smoothly.
- DO NOT short any circuits or electronic parts. An insulated turning tool MUST be used for all adjustments.
- DO NOT keep power ON for a long time when the transceiver is defective.
- DO NOT transmit power into a signal generator or a sweep generator.
- ALWAYS connect a 50 dB to 60 dB attenuator between the transceiver and a deviation meter or spectrum analyzer when using such test equipment.
- READ the instructions of test equipment thoroughly before connecting equipment to the transceiver.

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SECTION 1 SPECIFICATIONS

GENERAL

Frequency range

Version	Receive	Transmit
EUR, TPE, THA	144.000 - 146.000	144.000 - 146.000
ITA, SEA, LA	136.000 - 174.000*	136.000 - 174.000*
USA	136.000 - 174.000*	140.000 - 150.000*

· Mode

- Nomber of memory channel : 113 (incl.3pairs of scan edges, 3 log, 3 repeater and 1 call channel)
- : -10°C to +60°C; +14°F to +140°F · Usable temperature range

: FM

 Frequency resolution : 5, 10, 12.5, 15, 20, 25, 30 and 50 kHz

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- · Frequency stability
- · Power supply requirement
- Current drain (at 13.8 V DC) :

±10 ppm (-10	°C to +60°C; +14°F to +140°F)
13.8 V DC ±15	5 % (negative ground)	
Receive	Standby (squeiched)	0.8 A
	Max. audio	1.0 A
Transmit	at 55 W	12.0 A
	at 25 W (TPE version)	7.0 A
	at 10 W (THA version)	5.5 A
SO-239 (50 Q		

- Antenna connector Dimensions
- : 140(W)×40(H)×180(D) mm; 51/2(W)×19/16(H)×73/32(D) inch
- (projections not included) · Weight

: 1.2 kg; 2 lb 10 oz

TRANSMITTER Output power

Version	High	Middle	Low
except TPE, THA	55 W	10 W	5 W
TPE	25 W		5 W
THA	10 W		5 W

Modulation system

- : Variable reactance frequency
- Maximum frequency deviation : ±5.0/±2.5* kHz *Europe and Italy versions only : Less than -60 (-55*) dB *Thailand version only
- Spurious emissions
- Microphone connector : 8-pin modular (600 Ω)

RECEIVER

- · Receive system : Double-conversion superheterodyne
- : 1st Intermediate frequency 15.65 MHz 450 kHz 2nd
- Sensitivity (at 12 dB SINAD) : Loss than 0.18 µV

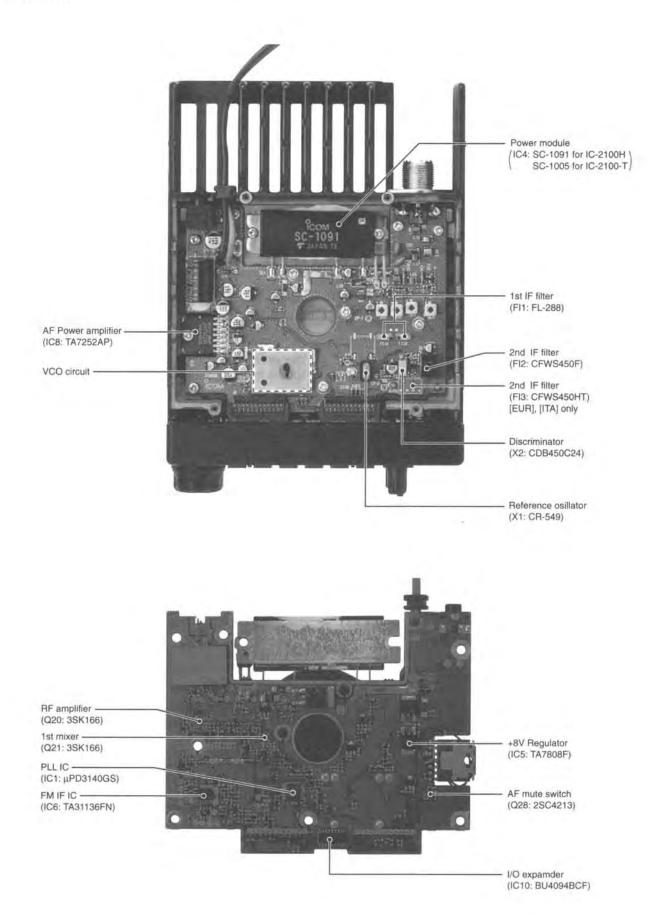
Squelch sensitivity (threshold) : Less than 0.13 μV

- Selectivity (wide/narrow) : More than 12/6* kHz at -6 dB Less than 28/18* kHz at -60 dB *Europe and Italy versions only
- · Spurious and image rejection : More than 60 dB
- · Intermodulation rejection retio : More than 70 dB
- Audio output power (at 13.8 V) : More than 2.4 W at 10% distortion with an 8Ω load
- External speaker connector : 3-conductor 3.5(d) mm (1/8")/8 Ω

All stated specifications are subject to change without notice or obligation.

SECTION 2 INSIDE VIEWS

MAIN UNIT



SECTION 3 CIRCUIT DESCRIPTION

3-1 RECEIVER CIRCUITS

3-1-1 ANTENNA SWITCHING CIRCUIT (MAIN unit)

The antenna switching circuit functions as a low-pass filter while receiving and a resonator circuit while transmitting. The circuit does not allow transmit signals to enter receiver circuits.

Received signals enter the antenna connector and pass through the low-pass filter (L17–L20, C55–C64). The filtered signals are passed through the $\lambda/4$ type antenna switching circuit (D10, D11, L22, L23) and are then applied to the RF amplifier (Q20).

3-1-2 SQUELCH ATTENUATOR

The attenuator circuit attenuates the signal strength to a maximum of 10 dB to protect the RF amplifier from distortion when excessively strong signals are received.

The current flow of the antenna switching circuit (D10, D11) is controlled by the [SQL] control via the attenuator controller (IC7). When the [SQL] control is rotated clockwise deeper than 12 o'clock, the current of D10 and D11 is increased. In this case, D10 and D11 act as an attenuator.

3-1-3 RF CIRCUIT (MAIN unit)

The RF circuit amplifies signals within the range of frequency coverage and filters out-of-band signals.

The signals from the antenna switching circuit pass through the tunable bandpass filter (D13). The filtered signals are amplified at the RF amplifier (Q20) and then enter another three-stage bandpass filters (D14–D16) to suppress unwanted signals. The filtered signals are applied to the 1st mixer circuit (Q21).

The tunable bandpass filters (D13–D16) employ varactor diodes to tune the center frequency of the RF passband for wide bandwidth receiving and good image response rejection. These diodes are controlled by the PLL lock voltage via the tune control circuit (IC2, D4).

3-1-4 1ST MIXER AND 1ST IF CIRCUITS (MAIN unit)

The 1st mixer circuit converts the received signals to a fixed frequency of the 1st IF signal with the PLL output frequency. By changing the PLL frequency, only the desired frequency will pass through a pair of crystal filters at the next stage of the 1st mixer.

The RF signals from the bandpass filter are applied to the 1st mixer circuit (Q21). The applied signals are mixed with the 1st LO signal coming from the RX-VCO circuit (Q33, D23) to produce a 15.65 MHz 1st IF signal. The 1st IF signal passes through a pair of crystal filters (FI1a/b) to suppress out-of-band signals. The filtered signal is amplified at the 1st IF amplifier (Q22) and applied to the 2nd IF circuit.

3-1-5 2ND IF AND DEMODULATOR CIRCUITS (MAIN unit)

The 2nd mixer circuit converts the 1st IF signal to a 2nd IF signal. A double-conversion superheterodyne system improves the image rejection ratio and obtains stable receiver gain.

The 1st IF signal from the IF amplifier (Q22) is applied to the 2nd mixer section of the FM IF IC (IC6, pin 16) and is then mixed with the 2nd LO signal for conversion to a 450 kHz 2nd IF signal.

IC6 contains the 2nd mixer, limiter amplifier, quadrature detector, S-meter detector, active filter and noise amplifier circuits, etc. A frequency from the PLL reference oscillator is used for the 2nd LO signal (15.2 MHz).

The 2nd IF signal from the 2nd mixer (IC6, pin 3) passes through the ceramic filter (FI2) (during wide channel spacing selection or passes through FI3 during narrow channel spacing selection; [EUR], [ITA] only). It is then amplified at the limiter amplifier section (IC6, pin 5) and applied to the quadrature detector section (IC6, pins 10, 11 and X2) to demodulate the 2nd IF signal into AF signals.

The AF signals are output from pin 9 (IC6) and are then applied to the AF amplifier circuit.

•2nd IF AND DEMODULATOR CIRCUITS

Squeich level adjustment R163 2nd IF filter 450 kHz (15.2 MHz) FI2 (FI3) WAR IN 5 PLL IC IC1 Noise 16 Activ detector Limiter filter amp FM Mixer RSSI 15.2 MHz detector IC6 TA31136F 10 14 16 11 1st IF (15.65 MHz) from Q22 SQL" signal Ι X2 to the CPU pin 97 T Ţ ORBV AF signal

3-1-6 AF CIRCUIT (MAIN unit)

The AF amplifier circuit amplifies the demodulated AF signals to drive a speaker.

The AF signals from IC6 (pin 9) are amplified at the active filters (Q23 HPF, Q24 LPF) and pass through the detector mute switch (Q25), and are level adjusted with the volume control on the LOGIC unit.

The AF amplifier IC8 amplifies the signals to a sufficient level to drive the speaker. The AF mute switch (Q28) turns ON to cut the signal to be input to the AF amplifier (IC8) during transmission.

3-1-7 SQUELCH CIRCUIT (MAIN and LOGIC units) • NOISE SQUELCH

The noise squelch circuit cuts out AF signals when no RF signals are received. By detecting noise components in the AF signals, the squelch circuit switches the AF mute switch.

A portion of the AF signals from the FM IF IC (IC6, pin 9) are applied to the active filter section (IC6, pin 8). The active filter section amplifies and filters noise components. The filtered signals are applied to the noise detector section and output from pin 14 as the "SQL" signal.

The "SQL" signal from IC6 (pin14) is applied to the CPU (LOGIC unit; IC1, pin 98). The CPU analyzes the noise condition and outputs the "RMUT" and "AMUT" signals via the I/O expander IC (LOGIC unit; IC10) to toggle the detector (Q25) and AF (Q28) mute switches.

Even when the squelch is closed, the AF mute switch (Q28) opens at the moment of emitting beep tones.

TONE SQUELCH

The tone squelch circuit detects AF signals and opens the squelch only when receiving a signal containing a matching subaudible tone (CTCSS). When tone squelch is in use, and a signal with a mismatched or no subaudible tone is received, the tone squelch circuit mutes the AF signals even when noise squelch is open.

A portion of the AF signals from the FM IF IC (IC6, pin 9) passes through the low-pass filter (LOGIC unit; IC6) to remove AF (voice) signals and is applied to the CTCSS decoder inside the CPU (LOGIC unit; IC1, pin 1) via the "TONEIN" line to control the DET and AF mute switches.

3-2 TRANSMITTER CIRCUIT

3-2-1 MICROPHONE AMPLIFIED (LOGIC unit)

The microphone amplifier circuit amplifies audio signals with +6 dB/octave pre-emphasis characteristics from the microphone to a level needed for the modulation circuit.

The AF signals from the microphone are adjusted for impedance-matching at the MIC sensitivity control circuit (IC4, D4). The adjusted signals pass through the MIC mute switch (Q4), and are then amplified at the microphone amplifier (Q5) and the limiter amplifier (IC5a) which has a negative feedback circuit for +6 dB/octave pre-emphasis.

The amplified signals are applied to the low-pass filter (IC5b) to filter out RF components and are then applied to the MAIN unit as the "MOD" signal.

3-2-2 MODULATION CIRCUIT (MAIN unit)

The modulation circuit modulates the VCO oscillating signal (RF signal) using the microphone audio signals.

The audio signals (MOD) change the reactance of D1 to modulate the oscillated signal at the TX-VCO circuit (Q1, Q2). The modulated signal is amplified at the buffer amplifier (Q4) and LO amplifier (Q5), then applied to the drive amplifiers.

3-2-3 DRIVE AMPLIFIER CIRCUIT (MAIN unit)

The drive amplifier circuit amplifies the VCO oscillating signal to the level needed at the power amplifier.

The RF signal from the LO amplifier (Q5) passes through the T/R switch (D5) and is amplified at the pre-drive (Q13) and drive (Q14) amplifiers. The amplified signal is applied to the power amplifier circuit.

3-2-4 POWER AMPLIFIER CIRCUIT (MAIN unit)

The power amplifier circuit amplifies the driver signal to an output power level.

The RF signal from the drive amplifier (Q14) is applied to the power module (IC4) to obtain 55 W (25 W for Taiwan version, 10 W for the IC-2100-T Thailand version) of RF power.

The amplified signals is passed through the antenna switching circuit (D7), APC detector circuit (L18, D8, D9), and lowpass filter (L19, L20, C62–C64) and is then applied to the antenna connector.

Collector voltages for the driver (Q13) and control voltage for the power amplifier (IC4, pin 2) are controlled by the APC circuit to protect the power module from a mismatched condition as well as to stabilize the output power.

3-2-5 APC CIRCUIT (MAIN unit)

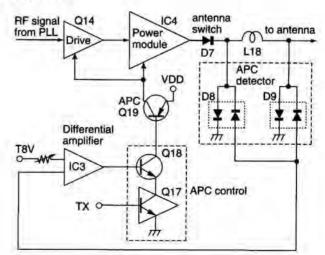
The APC circuit protects the power amplifier from a mismatched output load and stabilizes the output power.

The APC detector circuit (L10, D8, D9) detects forward signals and reflection signals at D8 and D9 respectively. The combined voltage is at minimum level when the antenna impedance is matched at 50 Ω and is increased when it is mismatched.

The detected voltage is applied to the differential amplifier (IC3, pin 3), and the power setting voltage is applied to the other input (pin 1) for the reference.

When antenna impedance is mismatched, the detected voltage exceeds the power setting voltage. The output voltage of the differential amplifier (IC3, pin 4) controls the input current of the power module (IC4) and drive amplifier (Q14) to reduce the output power via the APC controller (Q18, Q19).

APC circuit



3-3 PLL CIRCUITS 3-3-1 PLL CIRCUIT

A PLL circuit provides stable oscillation of the transmit frequency and the receive 1st LO frequency. The PLL circuit compares the phase of the divided VCO frequency to the reference frequency. The PLL output frequency is controlled by the divided ratio (N-data) of a programmable divider.

An oscillated signal from the VCO passes thorough the buffer amplifiers (Q4, Q6) is applied to the PLL IC (IC1, pin 2) and is prescaled in the PLL IC based on the divided ratio (Ndata). The reference signal is generated at the reference oscillator (X1) and is also applied to the PLL IC. The PLL IC detects the out-of-step phase using the reference frequency and outputs it from pin 8. The output signal is passed thorough the loop filter (R89, R90, C105, C107) and is then applied to the VCO circuit as the lock voltage.

The lock voltage is also used for the receiver tunable bandpass filters to match the filter's center frequency to the desired receive frequency. The lock voltage is applied to the bandpass filters (D13–D16) via the tune control circuit (IC4, D4).

3-3-2 VCO CIRCUIT (MAIN unit)

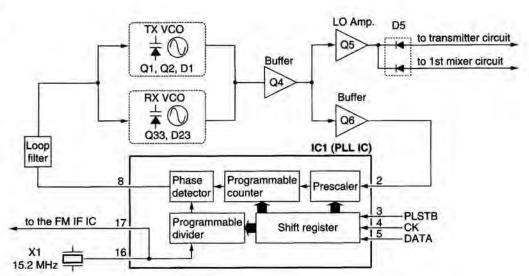
The VCO circuit contains a separate TX-VCO (Q1, Q2, D1) and RX-VCO (Q33, D23). The oscillated signal is amplified at the buffer (Q4) and LO (Q5) amplifiers, and is then applied to the T/R switching circuit (D5). Then the Tx and Rx signals are applied to the pre-driver (Q13) and 1st mixer (Q21) respectively.

A portion of the signal from Q4 is amplified at the buffer amplifier (Q6) and is then fed back to the PLL IC (IC1 pin 2) as the comparison signal.

3-4 POWER SUPPLY CIRCUITS VOLTAGE LINES

Line	Description		
н	The voltage from the connected DC power sup- ply.		
13.8V	The same voltage as the HV line which is con- trolled by the power switching circuit (Q25, Q26 Q35). When the [POWER] switch is pushed, the CPU outputs the "PWRON" control signal to the power switching circuit to turn the circuit ON.		
C5V	Common 5 V for the CPU converted from the HV line by the C5V regulator circuit (IC9). The circuit outputs the voltage regardless of the power ON/OFF condition.		
+8V	Common 8 V converted from the 13.8V line by the +8V regulator circuit (IC5).		
R8V	Receive 8 V controlled by the R8V regulator cir- cuit (Q29, Q30) using the "RX" signal from the I/O expander IC (IC10).		
T8V	Transmit 8 V controlled by the T8V regulator cir- cuit (Q11, Q12) using the "TX" signal from the I/C expander IC (IC10).		
+5V	Common 5 V converted from the +8V line by the +5V regulator circuit (Q31, Q32).		





3-5 PORT ALLOCATIONS 3-5-1 CPU (LOGIC UNIT IC1)

Pin number	Port name	Description		
1	TONEIN	nput port for the CTCSS decode sig nals.		
9	RES	Input port for the reset signal.		
11	ск	Outputs clock signal to the I/C expander ICs (IC10, MAIN unit; IC10) PLL IC (MAIN unit; IC1), etc.		
12	DATA	Outputs data signals to the I/C expander ICs (IC10, MAIN unit; IC10) PLL IC (MAIN unit; IC1), etc.		
13	ESCK	Outputs clock signal to the EEPRON (IC7).		
14	ESDA	I/O port for the EEPROM (IC7) data signals.		
16	RD	Input port for the cloning signal.		
17	TD	Output port for the cloning signal.		
18	PWRSW	Input for the POWER switch. Low : While POWER switch is pushed.		
19, 20	DLCK, DLUD	Input ports for up/down signals from main dial.		
22	EXSTB	Outputs strobe signals for the I/C expander ICs (IC10, MAIN unit; IC10)		
23	MICIN	Input port for microphone serial sig- nal via the buffer amplifier.		
24	PLSTB	Outputs strobe signals for the PLL IC (MAIN unit; IC1).		
25 E-TONE		Outputs 1750 Hz Europe tone signal.		
26	UNLK	Input port for PLL unlock signal fro the PLL IC (MAIN unit; IC1). High : During unlock		
33–35	COM3- COM1	Output LCD drive signals.		
36–39	KR0- KR3	Input ports for initial matrix.		
40	PWRON	Outputs power switching circuit con- trol signal. High : While turning power ON.		
41	COLOR	Outputs color control signal for display backlight. High : While display backlight is amber.		
42, 43	DIM0, DIM1	Outputs brightness control signal for display backlight.		
44-75	SEG9- SEG40	Output LCD drive signals.		
77-88	SEG41- SEG52	ouput tob unve signals.		
90	CTCSS	Outputs CTCSS signals.		
91	DTMF	Outputs DTMF signals.		

Pin number	Port name	Description			
93	PTT	Input port for the PTT switch. High : While PTT switch is pushed.			
94 EXTMIC 96 SQLV 97 SQL		Input port to detect remote microphon connection. Low : HM-90/98 is connected.			
		Input port for squelch setting level sig- nal.			
		Input port for squelch level signal.			
99	99 SMET Input port S-meter level signal.				
100	MICUD	Input ports for up/down signals from a microphone.			

3-5-2 I/O expander IC (1) IC10 (LOGIC unit)

Pin number	Port name	Description			
11	W/N	Outputs receive/transmit passband width control signal. High : While narrow bandwidth is selected. ([EUR], [ITA] only)			
12 MMUTE		Outputs MIC mute control signal. High : While DTMF signals are out- put, etc.			
13	AMUTE	Outputs AF mute switch (MAIN unit; Q28) control signal. High : While squelched.			
14	RMUTE	Outputs detector mute switch (MAIN unit; Q25) control signal. High : While squelched.			

Pin number	Port name		Description					
4	тх	Outputs the T8V regulator (Q11, Q12 control signal. Low : While transmitting						
		Output	RF power	control si	gnals.			
1.7	LP1, LP2			RF power				
5,6		1.000	High	Mid	Low			
1.5		LP1	Ĺ	L	н			
		LP2	L	н	L			
7	SHIFT	Outputs TX-VCO/RX-VCO select sig nal. High : While transmitting Outputs the R8V regulator (Q29, Q30 control signal. Low : While receiving						
14	RX							

(2) IC10 (MAIN unit)

SECTION 4 ADJUSTMENT PROCEDURES

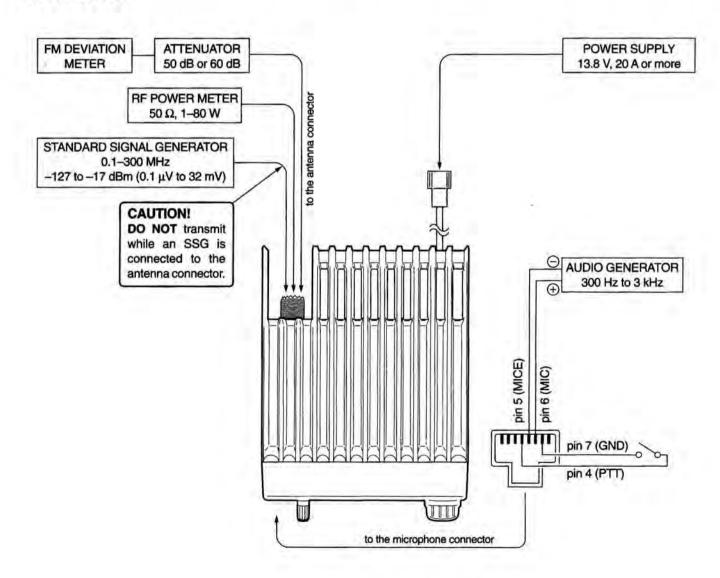
4-1 PREPARATION

All adjustments in this section must be performed on wide bandwidth condition unless specified otherwise. (Narrow bandwidth is selectable for Europe and Italy vertions only.)

REQUIRED TEST EQUIPMENT

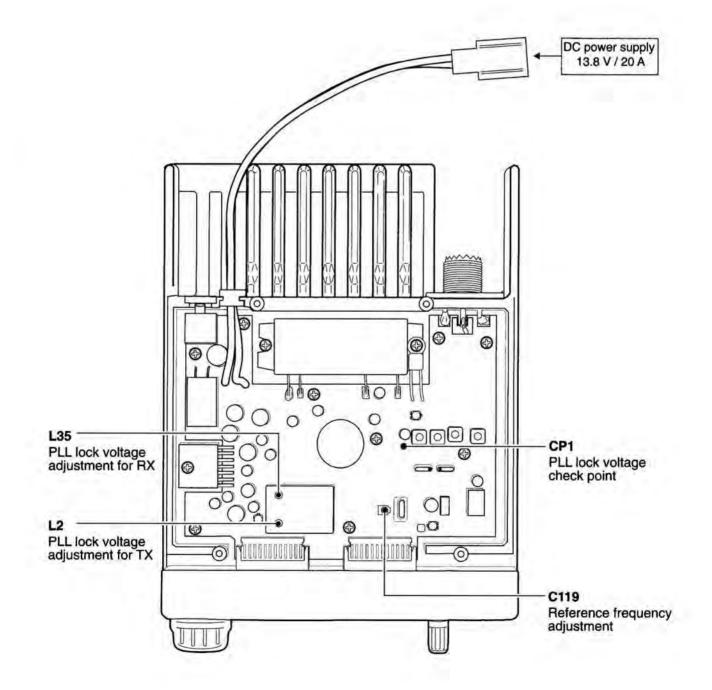
EQUIPMENT	GRADE	AND RANGE	EQUIPMENT	GRADE	AND RANGE
DC power supply		: 13.8 V DC : 20 A or more	Audio generator	Frequency range Measuring range	: 300–3000 Hz : 1–500 mV
Measuring range : 160 W RF power meter Frequency range : 100300 MHz (terminated type) Impedance : 50 Ω	: 100–300 MHz : 50 Ω	Standard signal generator (SSG)	Frequency range Output level	: 0.1–300 MHz : 0.1 µV–32 mV (–127 to –17 dBm)	
	Frequency range : Frequency accuracy :	: Less than 1.2 : 1 : 0.1–300 MHz : ±1 ppm or better : 100 mV or better	Oscilloscope	Frequency range Measuring range	: DC-20 MHz : 0.01-20 V
Frequency counter			AC millivoltmeter	Measuring range	: 10 mV-10 V
FM deviation meter	the desired the get	: 30-300 MHz : 0 to ±10 kHz	External speaker	Input impedance Capacity	: 8 Ω : 4 W or more
DC voltmeter		: 50 kΩ/V DC or better	Attenuator	Power attenuation Capacity	: 50 or 60 dB : 100 W or more

CONNECTION



4-2 PLL ADJUSTMENTS

ADJUSTMENT		ADJUSTMENT CONDITION	MEASUREMENT		VALUE	ADJUSTMENT POINT	
			UNIT LOCATION			UNIT	ADJUST
VOLTAGE	Displayed frequency : 145.000 MHz Receiving	MAIN	Connect a digital multi-meter or oscil- loscope to the check point CP1.			L35	
	2	Transmitting			1.45–1.55 V		L2
Pll Reference Frequency	1	 Displayed frequency : 145.000 MHz [EUR, TPE, THA] 146.000 MHz [ITA, USA, SEA, LA] Output power : Low Transmitting 	Rear Panel	Loosely couple the frequency counter to the antenna con- nector.	[EUR, TPE, THA]	MAIN	C119

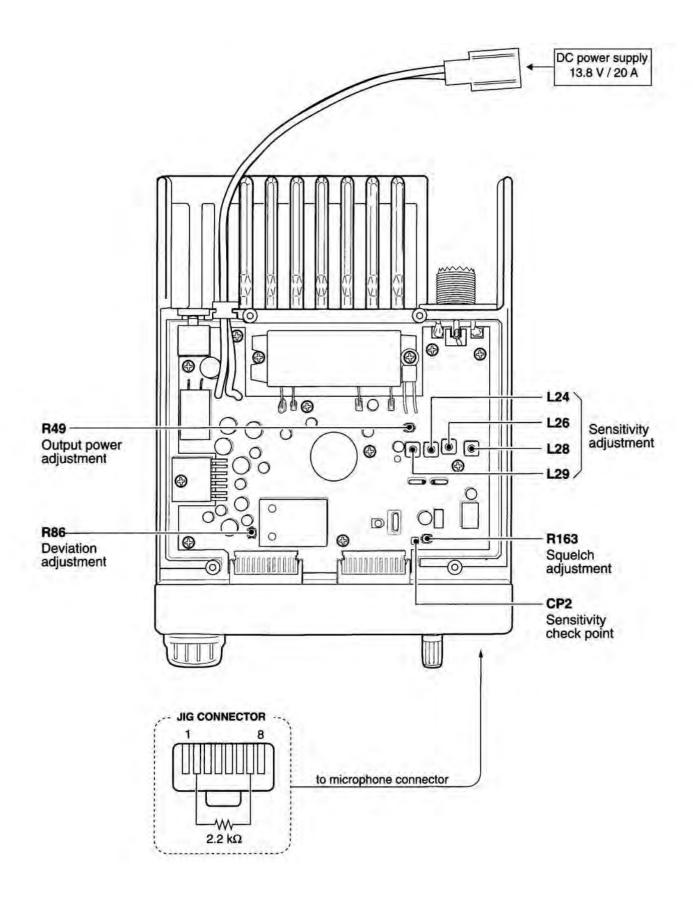


4-3 TRANSMITTER AND RECEIVER ADJUSTMENTS

The receiver adjustments must be performed after PLL ADJUSTMENTS.

ADJUSTMENT		ADJUSTMENT CONDITION	M	EASUREMENT	VALUE		ADJUSTMENT	
ADJUSTME		ADJUSTIMENT CONDITION	UNIT	LOCATION	TALUE	UNIT	ADJUST	
output Power	1	 Displayed frequency : 145.000 MHz [EUR, TPE, THA] 146.000 MHz [ITA, USA, SEA, LA] Output power : High Transmitting 	Rear Panel	Connect the RF power meter to the antenna connector.	25 W [TPE]	MAIN	R49	
FM DEVIATION	1	 Displayed frequency : 145.000 MHz [EUR, TPE, THA] 146.000 MHz [ITA, USA, SEA, LA] Output power : Low Connect an audio generator to the [MIC] connector and set as: 1 kHz/ 50 mV [USA] 1 kHz/ 20 mV [Other] TONE : OFF Set an FM deviation meter as: HPF : 50 Hz LPF : 20 kHz De-emphasis : OFF Detector : (P-P)/2 Transmitting 	Rear Panel	Connect an FM deviation meter to the antenna con- nector through an attenuator.	±4.8 kHz	MAIN	R86	
	2	IF bandwidth : Narrow [EUR, ITA] only Transmitting			±2.0-±3.0 kHz		Verify	
SENSITIVITY	1	 Displayed frequency : 145.000 MHz [EUR, TPE, THA] 146.000 MHz [ITA, USA, SEA, LA] Connect an SSG to the antenna connector and set as: Level : 32 µV* (-77 dBm) Deviation : ±3.5 kHz Modulation : 1 kHz Receiving 	MAIN	Connect a digital multimeter or oscil- loscope to check point CP2.	Maximum voltage	MAIN	Adjust in sequence repeated- ly. L24, L26, L28, L29	
Squelch/ S-Meter (Squelch)	1	 Turn into squelch/S-meter setting mode. Connect a JIG to the [MIC] connector, then turn power ON. Displayed frequency : 145.000 MHz [EUR, TPE, THA] 146.000 MHz [ITA, USA, SEA, LA] R163 : Max. clockwise Connect an SSG to the antenna connector and set as: Level : 0.071 µV* (-130 dBm) Deviation : ±3.5 kHz Modulation : 1 kHz Receiving 	Speaker		At the point where the signal just appears.	MAIN	R163	
(S-METER)	2	 Set an SSG as : Level : 1.0 μV* (-107 dBm) Deviation : ±3.5 kHz Modulation : 1 kHz Receiving 	Display	S/RF indicator	Push and hold the [S the [MW] key on the • Verify that S-mete	HM-98.		

*This output level of the standard signal generator (SSG) is indicated as SSG's open circuit.



SECTION 5 PARTS LIST

[LOGIC UNIT]

REF ORDER DESCRIPTION NO. NO. IC1 1140007020 S.IC HD6433875A83H [THA] only 1140007420 S.IC HD6433875A85H other 1110002860 S.IC TA75S393F (TE85R) IC2 1130004200 S.IC TC4S66F (TE85R) IC4 1110000960 NJM4558M(T1) IC5 S.IC IC6 1110000960 S.IC NJM4558M(T1) 24LC16BT-I/SN 1130007290 S.IC IC7 S-80945ALMP-DA9-T2 IC8 1110004750 S.IC 1130007700 BU4094BCF-T1 IC10 S.IC 1530002060 S.TRANSISTOR 2SC4081 T107 R Q1 Q2 1590001330 S.TRANSISTOR DTA114EUA T106 Q3 1540000250 S.TRANSISTOR 2SD999-T2 CK 1590001390 2SJ144-Y (TE85R) Q4 S.FET 2SC4081 T107 R Q5 1530002060 S.TRANSISTOR Q6 1530002060 S.TRANSISTOR 2SC4081 T107 R 2SJ144-Y (TE85R) 07 1590001390 S.FET S.TRANSISTOR DTC144EUA T106 1590000430 Q8 S.TRANSISTOR DTC144TU T107 1590000660 011 1590000430 S.TRANSISTOR **DTC144EUA T106** 018 2SC4116-BL(TE85R) S.TRANSISTOR 020 1530002850 [EUR], [ITA] only 2SC4081 T107 R 1530002060 S.TRANSISTOR 021 2SC4081 T107 R 1530002060 S.TRANSISTOR Q22 2SC4081 T107 R 1530002060 S.TRANSISTOR 023 2SC4081 T107 R 2SC4081 T107 R 1530002060 S.TRANSISTOR Q24 Q25 1530002060 S.TRANSISTOR 1590000430 S.TRANSISTOR **DTC144EUA T106** Q26 1510000510 S.TRANSISTOR 25A1576 AT106 B 027 1590000430 S.TRANSISTOR **DTC144EUA T106** Q28 1730002280 S.ZENER MA8091-M (TX) DI D2 1730002280 S.ZENER MA8091-M (TX) D3 1750000550 S.DIODE 1SS355 TE-17 D4 1750000550 S.DIODE 1SS355 TE-17 D5 1750000550 S.DIODE 1SS355 TE-17 D6 1730002280 S.ZENER MA8091-M (TX) D7 1750000550 S.DIODE 1SS355 TE-17 D9 1750000130 S.DIODE DA204U T107 D12 1160000060 S DIODE DAN202U T107 1160000060 S.DIODE D13 DAN202U T107 D14 1160000060 S.DIODE DAN202U T107 D15 1750000550 S.DIODE 1SS355 TE-17 [EUR], [TPE] D16 1710000600 DIODE 1SS254 1SS355 TE-17 D18 1750000550 S.DIODE [EUR], [TPE], [USA] THAT 1SS355 TE-17 D19 1750000550 S.DIODE D21 1160000060 S.DIODE DAN202U T107 [EUR] 1750000170 S.DIODE DA115 T107 [TPE], [THA] 1750000160 S.DIODE DA114 T107 [SEA] D22 1750000170 S.DIODE DA115 T107 [ITA] 1750000160 S.DIODE DA114 T107 [TPE] D23 1160000060 S.DIODE DAN202U T107 D24 1750000550 S.DIODE 1SS355 TE-17 D25 1750000550 S.DIODE 1SS355 TE-17 X1 6050009600 S.XTAL SMD-49 (8.000 MHz) 6200005950 S.COIL LQH 3N 2R2M04 (Q20) L1 6200004920 S.COIL MLF1608A 2R2K-T 12 6200004920 S.COIL MLF1608A 2R2K-T L3 6200004920 S.COIL 14 MLF1608A 2R2K-T 15 6200005950 S.COIL LOH 3N 2R2M04 (Q20) 6200004920 S.COIL MLF1608A 2R2K-T L6 MLF2012D R82K-T 6200001520 S.COIL L7 6200004920 S.COIL MLF1608A 2R2K-T L8 R1 7030003600 S.RESISTOR ERJ3GEYJ 223 V (22 kQ) R2 7030003560 S.RESISTOR ERJ3GEYJ 103 V (10 kΩ) 7030003480 S.RESISTOR B3 ERJ3GEYJ 222 V (2.2 kΩ)

[LOGIC UNIT]

REF NO.	ORDER NO,		DESCRIPTION
R4		S.RESISTOR	ERJ3GEYJ 104 V (100 kΩ)
R5	7030003390	S.RESISTOR	ERJ3GEYJ 391 V (390 Ω)
R6	7030001040	S.RESISTOR	MCR50JZHJ 18 Ω (180)
R7		S.RESISTOR	
R8		S.RESISTOR	ERJ3GEYJ 124 V (120 kΩ)
R9		S.RESISTOR	ERJ3GEYJ 472 V (4.7 kΩ)
R10		S.RESISTOR	ERJ3GEYJ 394 V (390 kΩ)
R11		S.RESISTOR	ERJ3GEYJ 103 V (10 kΩ)
R12		S.RESISTOR	ERJ3GEYJ 104 V (100 kΩ)
R13		S.RESISTOR	ERJ3GEYJ 104 V (100 kΩ)
R14		S.RESISTOR	ERJ3GEYJ 122 V (1.2 kΩ)
R15		S.RESISTOR	ERJ3GEYJ 101 V (100 Ω)
R16	7030003560	S.RESISTOR	
R17	7030003600	S.RESISTOR	ERJ3GEYJ 223 V (22 kΩ) [USA] only
	7030003510	S.RESISTOR	ERJ3GEYJ 392 V (3.9 kΩ) other
R18	7030003510	S.RESISTOR	ERJ3GEYJ 392 V (3.9 kΩ)
R19	7030003560	S.RESISTOR	ERJ3GEYJ 103 V (10 kΩ)
R20	7030003530	S.RESISTOR	ERJ3GEYJ 562 V (5.6 kΩ) [TPE], [USA] only
R21	7030003680	S.RESISTOR	ERJ3GEYJ 104 V (100 kΩ)
R22		S.RESISTOR	ERJ3GEYJ 104 V (100 kΩ)
R22		S.RESISTOR	ERJ3GEYJ 223 V (22 kΩ)
R24		S.RESISTOR	ERJ3GEYJ 470 V (47 Ω)
R24		S.RESISTOR	ERJ3GEYJ 681 V (680 Ω)
R25		S.RESISTOR	ERJ3GEYJ 101 V (100 Ω)
R26	7030003320		ERJ3GEYJ 331 V (330 Ω)
R28		S.RESISTOR	ERJ3GEYJ 474 V (470 kΩ)
R29		S.RESISTOR	ERJ3GEYJ 104 V (100 kΩ)
R30		S.RESISTOR	ERJ3GEYJ 473 V (47 kΩ)
R31	7030003730		ERJ3GEYJ 274 V (270 kΩ)
R32	7030003480	S.RESISTOR	ERJ3GEYJ 222 V (2.2 kΩ)
R33	7030003480	S.RESISTOR	ERJ3GEYJ 105 V (1 MΩ)
R34	1 T 2 K T 1 K K K K K K K K K K	S.RESISTOR	ERJ3GEYJ 103 V (10 kΩ)
R35	7030003560	S.RESISTOR	ERJ3GEYJ 103 V (10 kΩ)
R36	7030003560		ERJ3GEYJ 154 V (150 kΩ)
R37	7030003700	S.RESISTOR	ERJ3GEYJ 391 V (390 Ω)
R38	7030003390	S.RESISTOR	ERJ3GEYJ 824 V (820 kΩ)
R39	7030003790		ERJ3GEYJ 394 V (390 kΩ)
R40	7030003790	S.RESISTOR	ERJ3GEYJ 824 V (820 kΩ)
R41		S.RESISTOR	ERJ3GEYJ 183 V (18 kΩ)
R42	7030003560	S.RESISTOR	ERJ3GEYJ 103 V (10 kΩ)
R43	7030003570	S.RESISTOR	ERJ3GEYJ 123 V (12 kΩ)
R44	7030003630	S.RESISTOR	ERJ3GEYJ 393 V (39 kΩ)
R45	7030003520	S.RESISTOR	ERJ3GEYJ 472 V (4.7 kΩ)
R46		S.RESISTOR	ERJ3GEYJ 224 V (220 kg)
R47	7030003720	S.RESISTOR	ERJ3GEYJ 823 V (82 kΩ)
R48	7030003670		ERJ3GEYJ 823 V (82 kΩ)
R49		S.RESISTOR	ERJ3GEYJ 823 V (82 kΩ)
R50		S.RESISTOR	ERJ3GEYJ 103 V (10 kΩ)
R51		S.RESISTOR	ERJ3GEYJ 474 V (470 kΩ)
R52		S.RESISTOR	ERJ3GEYJ 105 V (1 MΩ)
R53		S.RESISTOR	ERJ3GEYJ 823 V (82 kΩ)
R54	100 C Y	S.RESISTOR	ERJ3GEYJ 823 V (82 kΩ)
R55	7030003670	S.RESISTOR	ERJ3GEYJ 823 V (82 kΩ)
R56	1123222222	S.RESISTOR	ERJ3GEYJ 124 V (120 kΩ)
R57	1.	S.RESISTOR	ERJ3GEYJ 474 V (470 kg)
R58		S.RESISTOR	ERJ3GEYJ 104 V (100 kg)
R59	A. A	S.RESISTOR	ERJ3GEYJ 105 V (1 MΩ)
R60		S.RESISTOR	ERJ3GEYJ 474 V (470 kg)
R61	7210001870		EVU-F2AF20 A14 (10KA)
R62	7210001860		EVU-F2AF20 B14 (10KB)
R64		S.RESISTOR	ERJ3GEYJ 472 V (4.7 kΩ)
R65		S.RESISTOR	ERJ3GEYJ 473 V (47 kΩ)
R66	7030003440	S.RESISTOR	ERJ3GEYJ 102 V (1 kQ)
R67		S.RESISTOR	ERJ3GEYJ 102 V (1 K2)
R68	7030003440	S.RESISTOR	ERJ3GEYJ 102 V (1 KΩ)
R69	Contract of the second second second	S.RESISTOR	ERJ3GEYJ 102 V (1 kΩ)
R70	7030003440	S.RESISTOR	ERJ3GEYJ 102 V (1 KΩ)
	7030003440		
R71		S.RESISTOR	ERJ3GEYJ 102 V (1 kΩ)
R73		S.RESISTOR	ERJ3GEYJ 102 V (1 kΩ)
R74		S.RESISTOR	ERJ3GEYJ 105 V (1 MΩ)
R75	1 million (1997) 1997 (1997) 1971	S.RESISTOR	ERJ3GEYJ 102 V (1 kΩ)
R76		S.RESISTOR	ERJ3GEYJ 102 V (1 kΩ)
R77	7030003440	S.RESISTOR	ERJ3GEYJ 102 V (1 kΩ)
R78	700000440	S.RESISTOR	ERJ3GEYJ 102 V (1 kΩ)

[LOGIC UNIT]

REF NO.	ORDER NO.		DESCRIPTION
R79	7030003440		ERJ3GEYJ 102 V (1 kΩ)
R80		S.RESISTOR	ERJ3GEYJ 102 V (1 kΩ)
R82	7030003560		ERJ3GEYJ 103 V (10 kΩ)
R83	7030003440		ERJ3GEYJ 102 V (1 kΩ)
R92	7030003560		ERJ3GEYJ 103 V (10 kΩ)
R93	7030003440	S.RESISTOR	ERJ3GEYJ 102 V (1 kΩ)
R94		S.RESISTOR	ERJ3GEYJ 102 V (1 kΩ)
R95	7030003440		ERJ3GEYJ 102 V (1 kΩ)
R96	7030003440		ERJ3GEYJ 102 V (1 kΩ)
R97		S.RESISTOR	ERJ3GEYJ 102 V (1 kΩ)
R98	7030003440		ERJ3GEYJ 102 V (1 kΩ)
R99	2,2,2,2,7,7,2,2,7,2,1	S.RESISTOR	ERJ3GEYJ 102 V (1 kΩ)
R100	7030003440		ERJ3GEYJ 102 V (1 kΩ)
R104	7030003580		ERJ3GEYJ 153 V (15 kΩ)
R124	7030003770 7030003320		ERJ3GEYJ 564 V (560 kΩ) ERJ3GEYJ 101 V (100 Ω)
R125	7030003320	S.RESISTOR	ERJ3GEYJ 102 V (1 kΩ)
R130 R133	and the second	S.RESISTOR	ERJ3GEYJ 822 V (8.2 kΩ)
H133	7030003550	S.RESISTUR	[EUR], [ITA] only
R134	7030003760	S.RESISTOR	ERJ3GEYJ 474 V (470 kΩ)
nio+	1000003100	Saleoloron	[EUR], [ITA] only
R135	7030003640	S.RESISTOR	ERJ3GEYJ 473 V(47 kΩ)
HISS	1050005040	U.ALDIOTON	[EUR], [ITA] only
R136	7030003560	S.RESISTOR	ERJ3GEYJ 103 V (10 kΩ)
R137	7030003560	S.RESISTOR	ERJ3GEYJ 103 V (10 kΩ)
R138	7030003560		ERJ3GEYJ 103 V (10 kΩ)
R143	7030003600		ERJ3GEYJ 223 V (22 kQ)
R144	7030003600	S.RESISTOR	ERJ3GEYJ 223 V (22 kΩ)
R145			ERJ3GEYJ 102 V (1 kΩ)
R148	7030003680	S.RESISTOR	ERJ3GEYJ 104 V (100 kQ)
R149		S.RESISTOR	ERJ3GEYJ 822 V (8.2 kg)
R150	7030003550		ERJ3GEYJ 822 V (8.2 kΩ)
R151		S.RESISTOR	ERJ3GEYJ 822 V (8.2 kΩ)
R152		S.RESISTOR	ERJ3GEYJ 473 V (47 kΩ)
R153	7030003520	S.RESISTOR	ERJ3GEYJ 472 V (4.7 kΩ)
R154		S.RESISTOR	ERJ3GEYJ 562 V (5.6 kΩ)
R155	7030003320		ERJ3GEYJ 101 V (100 Ω)
R156		S.RESISTOR	ERJ3GEYJ 680 V (68 Ω)
R157	7030003340	and the second se	ERJ3GEYJ 151 V (150 Ω)
R158	7030003410		ERJ3GEYJ 561 V (560 Ω)
R159	7030003460	S.RESISTOR	ERJ3GEYJ 152 V (1.5 kΩ)
R160	7030003320	S.RESISTOR	ERJ3GEYJ 101 V (100 Ω)
R161	7030003340	S.RESISTOR	ERJ3GEYJ 151 V (150 Ω)
R162	7030003370	S.RESISTOR	ERJ3GEYJ 271 V (270 Ω)
R163	7030003560	S.RESISTOR	ERJ3GEYJ 103 V (10 kΩ)
C1	4030006860	S.CERAMIC	C1608 JB 1H 102K-T-A
C2		S.CERAMIC	C1608 JB 1H 102K-T-A
C3		S.CERAMIC	C1608 JB 1H 102K-T-A
C4		S.CERAMIC	C1608 JB 1H 102K-T-A
C5	4030006860	S.CERAMIC	C1608 JB 1H 102K-T-A
C6	4030007090	S.CERAMIC	C1608 CH 1H 470J-T-A
C7	4030008630		C1608 JF 1C 104Z-T-A
C8	4510004630	and the second	
C9	4030006900		C1608 JB 1E 103K-T-A
C10	4510004630		
C11	4030008680	S.CERAMIC	C2012 JF 1C 105Z-T-A
C12	4030008630	S.CERAMIC	C1608 JF 1C 104Z-T-A
C13		S.CERAMIC	C1608 JB 1H 102K-T-A
C14	4510004630	S.ELECTROLYTIC	
C15	4030008900	S.CERAMIC	C1608 JB 1C 333K-T-A
C16	4030007020	S.CERAMIC	C1608 CH 1H 120J-T-A
C17	4030008680	S.CERAMIC	C2012 JF 1C 105Z-T-A
C18	4030009490	S.CERAMIC	C1608 JB 1H 821K-T-A
C19	4030008470	S.CERAMIC	C1608 JB 1H 272K-T-A
C20	4030007120	S.CERAMIC	C1608 CH 1H 820J-T-A
C21	4030007130	S.CERAMIC	C1608 CH 1H 101J-T-A
C22	4030006860	S.CERAMIC	C1608 JB 1H 102K-T-A
C23	4030008630	S.CERAMIC	C1608 JF 1C 104Z-T-A
C24	4510004630		
C25	4030008630	The second se	C1608 JF 1C 104Z-T-A
C26	4030008630		C1608 JF 1C 104Z-T-A
C27	4030008630	S.CERAMIC	C1608 JF 1C 104Z-T-A
C30	4030008630		C1608 JF 1C 104Z-T-A
C31	4030008680		C2012 JF 1C 105Z-T-A
C32	4030006860	S.CERAMIC	C1608 JB 1H 102K-T-A
C33	4030008630		C1608 JF 1C 104Z-T-A
C34	4030006860	S.CERAMIC	C1608 JB 1H 102K-T-A
120912111		S.CERAMIC	C1608 JF 1C 104Z-T-A
C35	4030008630		
120 01 21 11		S.CERAMIC S.CERAMIC	C1608 JB 1C 393K-T-A C1608 JF 1C 104Z-T-A

[LOGIC UNIT]

REF NO.	ORDER NO.	DESCRIPTION		
238		S.CERAMIC	C1608 JB 1H 152K-T-A	
239	4030008630	S.CERAMIC	C1608 JB 1H 152K-T-A C1608 JF 1C 104Z-T-A C1608 JF 1C 104Z-T-A C1608 JB 1E 103K-T-A C1608 CH 1H 101J-T-A C1608 CH 1H 470J-T-A C1608 JB 1H 102K-T-A C1608 JB 1H 102K-T-A C1608 JB 1H 102K-T-A C1608 JB 1E 103K-T-A C1608 JB 1E 103K-T-A C1608 JB 1H 102K-T-A C1608 CH 1H 040C-T-A C1608 CH 1H 040C-T-A C1608 CH 1H 040C-T-A C1608 JB 1H 102K-T-A C1608 JB	
240	4030008630	S.CERAMIC	C1608 JF 1C 104Z-T-A	
241	4030006900	S.CERAMIC	C1608 JB 1E 103K-T-A	
42	4030007130	SCERAMIC	C1608 CH 1H 101J-T-A	
245	4030007090	SCERAMIC	C1608 CH 1H 470.J-T-A	
248	4030006960	SCEBAMIC	C1608 JB 1H 102K-T-A	
240	40300000000	SCERAMIC	C1608 IB 1H 109K T A	
	4030008800	SCERAMIC	C1600 JD 11 102K-1-A	
250	4030006860	S.CERAMIC	C1000 JB 1H 102K-1-A	
251	4030006860	SUCERAMIC	C1608 JB TH 102K-T-A	
252	4030006900	S.CEHAMIC	C1608 JB 1E 103K-1-A	
253	4030006900	S.CEHAMIC	G1608 JB 1E 103K-T-A	
54	4030006860	S.CERAMIC	C1608 JB 1H 102K-T-A	
255	4030006950	S.CERAMIC	C1608 CH 1H 040C-T-A	
256	4030007050	S.CERAMIC	C1608 CH 1H 220J-T-A	
257	4030006860	S.CERAMIC	C1608 JB 1H 102K-T-A	
259	4030006900	S.CERAMIC	C1608 JB 1E 103K-T-A	
060	4510004630	S.ELECTROLYTIC	ECEV1CA100SR	
63	4030006900	S.CERAMIC	C1608 JB 1E 103K-T-A	
64	4030006900	S.CERAMIC	C1608 JB 1E 103K-T-A	
65	4030006900	S.CERAMIC	C1608 JB 1E 103K-T-A	
66	4030006860	SCEBAMIC	C1608 JB 1H 102K-T-A	
67	4030007000	SCERAMIC	C1608 CH 1H 470 LT.A	
	4030007030	SCEDAMIC	C1600 CH 1H 4701 T A	
68	4030007090	S.CERAMIC	C1008 CH 1H 4/00-1-A	
69	4030006860	S.CERAMIC	C1008 JB 1H 102K-1-A	
70	4030006860	S.CEHAMIC	C1608 JB 1H 102K-T-A	
71	4030006860	S.CERAMIC	C1608 JB 1H 102K-T-A	
72	4030007090	S.CERAMIC	C1608 CH 1H 470J-T-A	
273	4030007090	S.CERAMIC	C1608 CH 1H 470J-T-A	
274	4030006860	S.CERAMIC	C1608 JB 1H 102K-T-A	
75	4030006860	S.CERAMIC	C1608 JB 1H 102K-T-A	
76	4030006860	S.CERAMIC	C1608 JB 1H 102K-T-A	
77	4030006860	S.CERAMIC	C1608 JB 1H 102K-T-A	
78	4030006860	SCEBAMIC	C1608 JB 1H 102K-T-A	
79	4030007000	SCERAMIC	C1608 CH 1H 470 LT.A	
80	4030009630	SCERAMIC	G1608 JE 1C 1047-T-A	
281	4030000000000	SCERAMIC	C1608 IB 1H 100K T A	
82	40300000000	SCEPAMIC	C1608 IB 1H 102K T A	
	4030008800	C CEDANIC	C1600 JD 11 102K-1-A	
83	4030006860	SUCENAMIC	01000 JB 1H 102K-1-A	
84	4030006860	SUEMAMIC	01000 JB 1H 102K-1-A	
85	4030007090	S.CEHAMIC	C1608 CH 1H 470J-T-A	
286	4030006860	S.CERAMIC	C1608 JB 1E 103K-T-A ECEV1CA100SR C1608 JB 1E 103K-T-A C1608 JB 1E 103K-T-A C1608 JB 1E 103K-T-A C1608 JB 1E 103K-T-A C1608 CH 1H 470J-T-A C1608 CH 1H 470J-T-A C1608 JB 1H 102K-T-A C1608 JB 1H 102K-	
87	4030006860	S.CERAMIC	C1608 JB 1H 102K-T-A	
88	4030006900	S.CERAMIC	C1608 JB 1E 103K-T-A	
89	4510004630	S.ELECTROLYTIC	ECEV1CA100SR	
:90	4030008630	S.CERAMIC	C1608 JF 1C 104Z-T-A	
91	4030008630	S.CERAMIC	C1608 JF 1C 104Z-T-A	
92	4030008630	S.CERAMIC	C1608 JF 1C 104Z-T-A	
93	4030008880	S.CERAMIC	C1608 JF 1C 104Z-T-A C1608 JF 1C 104Z-T-A C1608 JF 1C 104Z-T-A C1608 JF 1C 104Z-T-A	
94	4030007090	S.CERAMIC	C1608 CH 1H 470J-T-A	
95		S.CERAMIC	C1608 CH 1H 680J-T-A	
IS1	5030001570	LCD	LD-HU10238E	
0S2	5040002060	S.LED	SML-020MLT TB6	
053	5040002060	T18 774141	SML-020MLT T86	
S3	5040002060		SML-020MLT T86	
S5	5040002060		SML-020MLT T86	
S6	5040002060		SML-020MLT T86	
S7	5040002060		SML-020MLT T86	
S8	5040002370		SML-010MT TB6	
089	5040002370		SML-010MT T86	
S10	5040002370	S.LED	SML-010MT T86	
S11	5040002370		SML-010MT T86	
S12	5040002370		SML-010MT T86	
S13	5040002370	THE LEADER AND A DESCRIPTION OF A DESCRI	SML-010MT T86	
1	2260002440	S.SWITCH	EVQ-PPPA25	
2		S.SWITCH	EVQ-PPPA25	
3		S.SWITCH	EVQ-PPPA25	
4	107555565.00T	S.SWITCH	EVQ-PPPA25	
5	Contraction of the second s		EVQ-PPPA25	
6	2260002440	S.SWITCH	EVQ-PPPA25	
37	2260002440	S.SWITCH	EVQ-PPPA25	
88	2260002440	and the first state of the second state of the	EVQ-PPPA25	
9	2250000370	ENCODER	EVQ-VENF0124B	
		CONVECTOR	95003-2881	
1	6450001470			
1	6450001470	The second s		
1	6510020880	CONNECTOR	53244-1217 53244-1217	

[LOGIC UNIT]

REF NO.	ORDER NO.	1	DESCRIPTION	
W1	7120000470	JUMPER	ERDS2T0	[THA] only
EP1 EP2	0910049542 8930045730	PCB LCD CONTACT	B 5097B SRCN-2088-S	P-N-W

[MAIN UNIT]

REF NO.	ORDER NO.		DESCRIPTION
IC1	1130007610	S.IC	µPD3140GS-E1 (DS8)
IC2	1130008560	S.IC	TC75S51F (TE85L)
IC3	1110002750	S.IC	TA75S01F (TE85R)
IC4	1150000130	IC	SC-1005 [THA] only
100	1150001950		SC-1091 other
105	1180001250	A State of the second sec	TA7808F(TE16L)
IC6	1110003490		TA31136FN (D,EL)
IC7	1110002750	S.IC	TA75S01F (TE85R)
IC8	1110002550	IC	TA7252AP
1C9	1180000420	S.IC	TA78L05F (TE12R)
IC10	1130007700	S.IC	BU4094BCF-T1
IC11	1140003830	S.IC	TC4W66F(TE12L)
	CONTROL 11		[EUR], [ITA] only
IC12	1140003830	S.IC	TC4W66F(TE12L)
			[EUR], [ITA] only
Q1	1530002920	S.TRANSISTOR	2SC4226-T2 R25
02	1530002920		2SC4226-T2 R25
			DTA113ZU T107
Q3	1590001040		
Q4	1530002920		2SC4226-T2 R25
Q5		S.TRANSISTOR	2SC4226-T2 R25
Q6	1530002920		2SC4226-T2 R25
Q7	1530002060	S.TRANSISTOR	2SC4081 T107 R
Q11	1530002850	S.TRANSISTOR	2SC4116-BL (TE85R)
Q12	1510000690		2SA1734 (TE12R)
Q13		S.TRANSISTOR	2SC3357-T2
Q14	1530002340		2SC2954-T2B
Q15		S.TRANSISTOR	DTC144EUA T106
10.200	10000000000000000000000000000000000000		
Q16		S.TRANSISTOR	DTC144EUA T106
Q17		S.TRANSISTOR	2SC4116-BL (TE85R)
Q18	and the second sec	S.TRANSISTOR	2SC4081 T107 S
Q19	1520000730	S.TRANSISTOR	2SB934P (DS)-(TX)
Q20	1580000490	S.FET	3SK166-2-T7
Q21	1580000490		3SK166-2-T7
Q22		S.TRANSISTOR	2SC4215-O (TE85R)
Q23	1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1	S.TRANSISTOR	2SC4081 T107 R
Q24	1530002060	and the second se	2SC4081 T107 R
			2SJ144-Y (TE85R)
Q25	1590001390	the second s	
Q26	1530002970		2SC4684 (TE16R)
Q27		S.TRANSISTOR	DTA143TU T107
Q28		S.TRANSISTOR	2SC4213-B (TE85R)
Q29	1590000980		DTB123EK T147
Q30	1590000430	S.TRANSISTOR	DTC144EUA T106
Q31		S.TRANSISTOR	DTB123EK T147
Q32	1.5.5.5.5.5.5.5.5.5.5.5.5	S.TRANSISTOR	DTC144EUA T106
Q33		S.TRANSISTOR	2SC4226-T2 R25
Q35	1590001320	S.TRANSISTOR	DTC143ZUA T106
1 A A A A A A A A A A A A A A A A A A A		S.TRANSISTOR	
Q36	1530002850	and the second se	
Q37		S.TRANSISTOR	2SC4116-BL (TE85R)
Q38	(S.TRANSISTOR	2SC4116-BL (TE85R) [EUR], [ITA] only
Q40		S.TRANSISTOR	[EUR], [ITA] only
Q42	1560000840	S.FET	2SK1829 (TE85R) [EUR], [ITA] only
D1		S.VARICAP	HVU350TRF
D3	1750000550	S.DIODE	1SS355 TE-17
D4	1790000980		MA742 (TX)
D5	1790000450	S.DIODE	MA862 (TX)
D6	1750000370	S.DIODE	DA221 TL
D7	1710000310	CALL CONTRACTOR	MI407
D8	1790000980		MA742 (TX)
D9	1790000980		MA742 (TX)
D10	1710000290	DIODE	MI308

[MAIN UNIT]

REF	ORDER NO.		DESCRIPTION
D12	1750000550	S.DIODE	1SS355 TE-17
D13		S.VARICAP	HVU350TRF
D14	1720000370	S.VARICAP	HVU350TRF
D15	1720000370	S.VARICAP	HVU350TRF
D16	1720000370	S.VARICAP	HVU350TRF
D17	1790000980		MA742 (TX)
D18	1730002340	S.ZENER	MA8047-M (TX)
D19	1750000550	S.DIODE	1SS355 TE-17
D20	1790000700		DSA3A1
D21	1750000550		1SS355 TE-17
D23		S.VARICAP	HVU350TRF
D24	1730000520	The second se	RD20E B2
D25	1750000550	S.DIODE	1SS355 TE-17
FI1	2010002240	MONOLITHIC	FL-288 (15.650 MHz)
FI2	2020001520	CERAMIC	CFWS450F
FI3	2020001460	CERAMIC	CFWS450HT [EUR], [ITA] only
X1 X2	6050009820	XTAL DISCRIMINATOR	CR-549 (15.2 MHz) CDB450C24
	0070000200		
L1	6200004480		MLF1608D R82K-T LB-277
L2 L3	6130002480 6200003300		ELJNC R22K-F
14	6200003300		ELJNC R22K-F
L4 L5	6200003300		ELJFC 1ROK-F
LG	6200001620		ELJFC 8R2K-F
L10	6200007380		ELJRE 47NG-F
L10	6200005740		ELJRE 18NG-F
L12	6200005690		ELJRE 68NG-F
L13	6200005710		ELJRE 27NG-F
L14	6200006670		ELJRE 68NG-F
L15	6200005740		ELJRE 47NG-F
L16	6170000180	COIL	LW-19
L17	6110001550		LA-235
L18	6110001560		LA-236
L19	6110001610		LA-244
L20	6110001550		LA-235
121	6200004480		MLF1608D R82K-T
L22	6110001550		LA-235
L23	6110001550		LA-235
124	6200004860	S.COIL	MC152-E558CNA-100036
125	6200002180	S.COIL	NL 252018T-R12J
126	6200004860	S.COIL	MC152-E558CNA-100036
127	6200004230		ELJNC R56K-F
128	6200004860	S.COIL	MC152-E558CNA-100036
129	6200004860	S.COIL	MC152-E558CNA-100036
L30	6200001920	S.COIL	ELJNC R15K-F
L31	6200003300	S.COIL	ELJNC R22K-F
L32	6200007850	S.COIL	ELJNG R82K-F
L33	6200002940	S.COIL	ELJFC 1R2K-F
L34	6200004480	and the second sec	MLF1608D R82K-T
L35	6200004850		MC152-E558CN-100024
L36	6200004450		ELJFC 6R8M-F
L37	6200004880		ELJFC 3R3K-F
L38 L39	6200004920 6200004920	S.COIL S.COIL	MLF1608A 2R2K-T MLF1608A 2R2K-T
		No. of the second s	NATE AND ADDRESS OF ADDRESS OF
R1	7030003690	S.RESISTOR	ERJ3GEYJ 124 V (120 kΩ)
R2	7030003320	S.RESISTOR	ERJ3GEYJ 101 V (100 Ω)
R6	7030003400	S.RESISTOR	ERJ3GEYJ 471 V (470 Ω)
R7	7030003620		ERJ3GEYJ 333 V (33 kΩ)
R8		S.RESISTOR	ERJ3GEYJ 471 V (470 Ω)
R9		S.RESISTOR	ERJ3GEYJ 333 V (33 kΩ)
R10	7030003320		ERJ3GEYJ 101 V (100 Ω)
R11	7030003320		ERJ3GEYJ 101 V (100 Ω)
R12	7030003690	En la contra da contr	ERJ3GEYJ 124 V (120 kΩ)
R13	UN TRACTORY TRACKS	S.RESISTOR	ERJ3GEYJ 272 V (2.7 kΩ)
R14	7030003320	1500 CT 5360 L 41 1	ERJ3GEYJ 101 V (100 Ω) ERJ3GEYJ 470 V (47 Ω)
R15	7030003280 7030003320	S.RESISTOR S.RESISTOR	ERJ3GEYJ 4/0 V (4/ Ω) ERJ3GEYJ 101 V (100 Ω)
R16 R17	7030003320		ERJ3GEYJ 470 V (47 Ω)
R18		S.RESISTOR	ERJ3GEYJ 473 V (47 kΩ)
	7030003840		ERJ3GEYJ 331 V (330 Ω)
R10		S.RESISTOR	ERJ3GEYJ 333 V (33 kΩ)
R19 R20		o, neolo I U n	
R20	7030003620		EBJ3GEV1 472 V (4.7 kO)
R20 R21	7030003520	S.RESISTOR	ERJ3GEYJ 472 V (4.7 kΩ) ERJ3GEYJ 225 V (2.2 MΩ)
R20	7030003520 7030003840	S.RESISTOR	ERJ3GEYJ 472 V (4.7 kΩ) ERJ3GEYJ 225 V (2.2 MΩ) ERJ3GEYJ 225 V (2.2 MΩ)

[MAIN UNIT]

REF NO.	ORDER NO.	DESCRIPTION		
R24		S.RESISTOR	ERJ3GEYJ 474 V (470 kΩ)	
R25	7030003420	S.RESISTOR	ERJ3GEYJ 681 V (680 Q)	
R26	7510000420	S.THERMISTOR	TN20-3W472LT	
R27	7030003480		ERJ3GEYJ 222 V (2.2 kΩ)	
R28	7030003480		ERJ3GEYJ 222 V (2.2 kΩ)	
R29	CLUSTER COMPANY	S.RESISTOR	ERJ3GEYJ 472 V (4.7 kΩ)	
R30	7030003520		ERJ3GEYJ 472 V (4.7 kΩ)	
R31	7030003520	C 14, 1212 VOL 2 C 17		
	7030003320		ERJ3GEYJ 472 V (4.7 kΩ)	
R32		A 11 1 1 1 1 1 1 1 1 1 1 1 1	ERJ3GEYJ 101 V (100 Ω) ERJ3GEYJ 680 V (68 Ω)	
R33	7030003300			
R34	7030003320	S.RESISTOR	ERJ3GEYJ 101 V (100 Ω)	
R35		S.RESISTOR	MCR10EZHJ 22 Ω (220)	
R36	7030003520		ERJ3GEYJ 472 V (4.7 kΩ)	
R37	7030003440	S.RESISTOR	ERJ3GEYJ 102 V (1 kΩ)	
R38	7030003440	S.RESISTOR	ERJ3GEYJ 102 V (1 kΩ)	
R39	7030003520	S.RESISTOR	ERJ3GEYJ 472 V (4.7 kΩ)	
R40	7030003430	S.RESISTOR	ERJ3GEYJ 821 V (820 Ω)	
R41	7030001130	S.RESISTOR	MCR50JZHJ 100 Ω (101)	
R42	7030000180	S.RESISTOR	MCR10EZHJ 22 Q (220)	
R43	7030003320		ERJ3GEYJ 101 V (100 Ω)	
R44	7030003600		ERJ3GEYJ 223 V (22 kΩ)	
R45		S.RESISTOR	ERJ3GEYJ 682 V (6.8 kΩ)	
R46	7030003540		ERJ3GEYJ 152 V (0.8 kΩ)	
R40		S.RESISTOR	ERJ3GEYJ 472 V (1.5 KΩ)	
			[TPE] onl	
	7030003490	S.RESISTOR	ERJ3GEYJ 272 V (2.7 kg) othe	
R48	7030003520	S.RESISTOR	ERJ3GEYJ 472 V (4.7 kΩ)	
R49	7310002740		RV-150 (RH03A3A14X0FC)103	
R50	1112 0 2 2 2 1	S.RESISTOR	ERJ3GEYJ 105 V (1 MΩ)	
R51	7520000120	2.	PTH9M04 BC 222TS-2F333	
R52		S.RESISTOR	ERJ3GEYJ 824 V (820 kΩ)	
R53	1.0000000000	S.RESISTOR	ERJ3GEYJ 103 V (10 kΩ)	
R54		S.RESISTOR	ERJ3GEYJ 473 V (47 kΩ)	
R55		S.RESISTOR	ERJ3GEYJ 333 V (33 kΩ)	
R56	7030001190	S.RESISTOR	MCR50JZHJ 330 Q (331)	
	11,202,302,5,402,51			
R57	1.00000000000	S.RESISTOR	ERJ3GEYJ 103 V (10 kΩ)	
R58	7030001110	S.RESISTOR	MCR50JZHJ 68 Ω (680)	
		C DECISTOR	[THA] only	
-		S.RESISTOR	MCR50JZHJ 22 Ω (220) othe	
R59		S.RESISTOR	ERJ3GEYJ 101 V (100 Ω)	
R60	Contraction of the second s	S.RESISTOR	ERJ3GEYJ 682 V (6.8 kΩ)	
R61	1.1.1.1.1.0.0.0.0.0.0.0.0.0.0.0.0.0.0.0	S.RESISTOR	ERJ3GEYJ 822 V (8.2 kΩ)	
R62		S.RESISTOR	ERJ3GEYJ 822 V (8.2 kΩ)	
R63	1.48444466644	S.RESISTOR	ERJ3GEYJ 682 V (6.8 kΩ)	
R64		S.RESISTOR	ERJ3GEYJ 224 V (220 kΩ)	
R66		S.RESISTOR	ERJ3GEYJ 473 V (47 kΩ)	
R67		S.RESISTOR	ERJ3GEYJ 104 V (100 kΩ)	
R68		S.RESISTOR	ERJ3GEYJ 151 V (150 Ω)	
R69	7030003440	S.RESISTOR	ERJ3GEYJ 102 V (1 kΩ)	
R70	7030003720	S.RESISTOR	ERJ3GEYJ 224 V (220 kΩ)	
R71	7030003720	S.RESISTOR	ERJ3GEYJ 224 V (220 kΩ)	
R72	7030003720	S.RESISTOR	ERJ3GEYJ 224 V (220 kΩ)	
R73	10101077311000	S.RESISTOR	ERJ3GEYJ 104 V (100 kΩ)	
R74		S.RESISTOR	ERJ3GEYJ 271 V (270 Ω)	
R75		S.RESISTOR	ERJ3GEYJ 180 V (18 Ω)	
R76		S.RESISTOR	ERJ3GEYJ 271 V (270 Ω)	
R77		S.RESISTOR	ERJ3GEYJ 104 V (100 kΩ)	
R78	and the second sec	S.RESISTOR	ERJ3GEYJ 680 V (68 Ω)	
R80	1.1.1.1.1.1.1.1.1.1.1.1.1.1.1.1.1.1.1.	S.RESISTOR	ERJ3GEYJ 101 V (100 Ω)	
R81		S.RESISTOR	ERJ3GEYJ 821 V (820 Ω)	
R82	T (T) A C (A, A, A) Y (2 A, B)	S.RESISTOR	ERJ3GEYJ 182 V (1.8 kΩ)	
R83		S.RESISTOR	ERJ3GEYJ 823 V (82 kΩ)	
R85		S.RESISTOR	ERJ3GEYJ 101 V (100 Ω)	
R86	7310002580		RV-108 (RH03A3A15X05A) 104	
R89		S.RESISTOR	ERJ3GEYJ 562 V (5.6 kΩ)	
R90		S.RESISTOR	ERJ3GEYJ 102 V (1 kΩ)	
R91		S.RESISTOR	ERJ3GEYJ 272 V (2.7 kΩ)	
R92	11 - 5 - 5 - 5 - 5 - 5 - 5 - 5 - 5 - 5 -	S.RESISTOR	ERJ3GEYJ 331 V (330 Ω)	
R93		S.RESISTOR	ERJ3GEYJ 104 V (100 kΩ)	
R98		S.RESISTOR	ERJ3GEYJ 223 V (22 kΩ)	
R100		S.RESISTOR	ERJ3GEYJ 821 V (820 Ω)	
R101	7030003370	S.RESISTOR	ERJ3GEYJ 271 V (270 Ω)	
R102		S.RESISTOR	ERJ3GEYJ 561 V (560 Ω)	
R103	The second s	S.RESISTOR	MCR10EZHJ 100 Q (101)	
R104		S.RESISTOR	ERJ3GEYJ 222 V (2.2 kΩ)	
		1.00.37.37	[EUR], [ITA] only	
2711	7030003420	S.RESISTOR	ERJ3GEYJ 681 V (680 Ω) othe	
R105		S.RESISTOR	ERJ3GEYJ 103 V (10 kΩ)	
R106		S.RESISTOR	ERJ3GEYJ 471 V (470 Ω)	
R107	A DESCRIPTION OF THE	S.RESISTOR	ERJ3GEYJ 473 V (47 kΩ)	
		S.RESISTOR	ERJ3GEYJ 154 V (150 kΩ)	
R108			an income to the r (100 has)	

[MAIN UNIT]

REF NO.	ORDER NO.		DESCRIPTION
R110		S.RESISTOR	ERJ3GEYJ 333 V (33 kΩ)
R111	7510000830	S.THERMISTOR	NTCCF2012 3EH 471KC-T
	7030000140	S.RESISTOR	[EUR], [ITA] only MCR10EZHJ 10 Ω (100) other
R113	7030003550	S.RESISTOR	ERJ3GEYJ 822 V (8.2 kΩ)
R114		S.RESISTOR	ERJ3GEYJ 123 V (12 kΩ)
R115	7030003600	S.RESISTOR	ERJ3GEYJ 223 V (22 kΩ)
R116		S.RESISTOR	ERJ3GEYJ 393 V (39 kΩ)
R117	7030003560		ERJ3GEYJ 103 V (10 kΩ)
R118 R119	7030003840 7030003380	S.RESISTOR	ERJ3GEYJ 225 V (2.2 MΩ) ERJ3GEYJ 331 V (330 Ω)
R120	7030003600		ERJ3GEYJ 223 V (22 kΩ)
R121		S.RESISTOR	ERJ3GEYJ 473 V (47 kΩ)
R122	101000000000000000000000000000000000000	S.RESISTOR	ERJ3GEYJ 102 V (1 kΩ)
R123		S.RESISTOR	ERJ3GEYJ 474 V (470 kΩ)
R124	V. C. C. C. S. C. R. J. L. L.	S.RESISTOR	ERJ3GEYJ 152 V (1.5 kΩ)
R125 R126	7030003680	a contraction of the second	ERJ3GEYJ 104 V (100 kΩ) ERJ3GEYJ 104 V (100 kΩ)
R127	7030003620		ERJ3GEYJ 333 V (33 kΩ)
R128		S.RESISTOR	ERJ3GEYJ 104 V (100 kΩ)
R129	7030003610	S.RESISTOR	ERJ3GEYJ 273 V (27 kΩ)
R130	7030003680		ERJ3GEYJ 104 V (100 kΩ)
R131	7030003680		ERJ3GEYJ 104 V (100 kΩ)
R132	7030003690	S.RESISTOR S.RESISTOR	ERJ3GEYJ 124 V (120 kΩ) MCR50JZHJ 10 Ω (100)
R133 R134		S.RESISTOR	ERJ3GEYJ 102 V (1 kΩ)
R136		S.RESISTOR	ERJ3GEYJ 333 V (33 kΩ)
R137	7030003560	S.RESISTOR	ERJ3GEYJ 103 V (10 kΩ)
R138	7030003560	S.RESISTOR	ERJ3GEYJ 103 V (10 kΩ)
R139	A STATE AND A STATE OF	S.RESISTOR	ERJ3GEYJ 220 V (22 Ω)
R140	7030003670		ERJ3GEYJ 823 V (82 kΩ)
R141		S.RESISTOR	ERJ3GEYJ 4R7 V (4.7 Ω)
R142 R145	7030003490 7030003560	S.RESISTOR S.RESISTOR	ERJ3GEYJ 272 V (2.7 kΩ) ERJ3GEYJ 103 V (10 kΩ)
R146	7030003200	S.RESISTOR	ERJ3GEYJ 100 V (10 Ω)
R148	7030003530	S.RESISTOR	ERJ3GEYJ 562 V (5.6 kΩ)
R149	7030003440	S.RESISTOR	ERJ3GEYJ 102 V (1 kΩ)
R150	7030003440	S.RESISTOR	ERJ3GEYJ 102 V (1 kΩ)
R151	7030003680	S.RESISTOR	ERJ3GEYJ 104 V (100 kΩ)
R152 R154	7030003570 7030003560	S.RESISTOR S.RESISTOR	ERJ3GEYJ 123 V (12 kΩ) ERJ3GEYJ 103 V (10 kΩ)
R155	7030003450	S.RESISTOR	ERJ3GEYJ 122 V (1.2 kΩ)
(1166		autosenariati	[EUR], [ITA] only
R156	7030003640	S.RESISTOR	ERJ3GEYJ 473 V (47 kΩ)
-			[EUR], [ITA] only
R157	7030003640	S.RESISTOR	ERJ3GEYJ 473 V (47 kΩ)
R159	7030003600	S.RESISTOR	[EUR], [ITA] only ERJ3GEYJ 223 V (22 kΩ)
R160		S.RESISTOR	ERJ3GEYJ 822 V (8.2 kΩ)
100.22	100000		[EUR], [ITA] only
R161	7030003680	S.RESISTOR	ERJ3GEYJ 104 V (100 kΩ)
2.20			[EUR], [ITA] only
R163	10 TO CO	S.TRIMMER	RV-150 (RH03A3A14X0FC) 103
R164 R165		S.THERMISTOR S.RESISTOR	NTCCM1608 4LH 104KC ERJ3GEYJ 683 V (68 kΩ)
R166	12.8 0 8 6 8 9 8 5 8 4	S.RESISTOR	ERJ3GEYJ 331 V (330 Ω)
R167		S.RESISTOR	ERJ3GEYJ 103 V (10 kΩ)
R168	7030003560	S.RESISTOR	ERJ3GEYJ 103 V (10 kΩ)
111	1.000		and second light the
C1	4030006860	SCERAMIC	C1608 IB 1H 100K T 4
C1 C2	4030006860		C1608 JB 1H 102K-T-A C1608 CH 1H 220J-T-A
C3	4030006860		C1608 JB 1H 102K-T-A
C6	4030006860		C1608 JB 1H 102K-T-A
C7	4030006910		C1608 CH 1H 0R5C-T-A
C8	4030006860		C1608 JB 1H 102K-T-A
C9		S.CERAMIC	C1608 CH 1H 0R3B-T-A
C10 C11	4030006860 4030006860		C1608 JB 1H 102K-T-A C1608 JB 1H 102K-T-A
C13	4030006910		C1608 CH 1H 0R5C-T-A
C14	4030006860		C1608 JB 1H 102K-T-A
C15	4030006860	S.CERAMIC	C1608 JB 1H 102K-T-A
C16	4030007060		C1608 CH 1H 270J-T-A
C17	4030006970		C1608 CH 1H 060D-T-A
C18 C19	4030007060 4030006860	S.CERAMIC	C1608 CH 1H 270J-T-A C1608 JB 1H 102K-T-A
C20	4030006860		C1608 CH 1H 1R5C-T-A
C21	4030006860		C1608 JB 1H 102K-T-A
C22	4030006860		C1608 JB 1H 102K-T-A
C23	4030006860		C1608 JB 1H 102K-T-A
C24		S.ELECTROLYTIC	ECEVICA100SR
C25	4030006860	S.GEHAMIG	C1608 JB 1H 102K-T-A

[MAIN UNIT]

REF NO.	ORDER NO.		DESCRIPTION	
C26		S.CERAMIC	C1608 JB 1H 102K-T-A	
C27	4030006860	S.CERAMIC	C1608 JB 1H 102K-T-A	
C28		S.CERAMIC		
C29 C30	The second se	S.CERAMIC S.CERAMIC	C1608 JB 1H 102K-T-A C1608 JB 1H 102K-T-A	
C31	and the second sec	S.TANTALUM	and the second se	
C32		S.CERAMIC	C1608 JB 1H 102K-T-A	
C33		S.CERAMIC	C1608 CH 1H 220J-T-A	
C34	4030007050	S.CERAMIC	C1608 CH 1H 220J-T-A	
C35	10	S.CERAMIC	C1608 JB 1H 102K-T-A	
C36		S.CERAMIC	C1608 JB 1H 102K-T-A	
C37 C39		S.CERAMIC S.CERAMIC	C1608 JB 1H 102K-T-A C1608 JB 1H 102K-T-A	
C40		S.CERAMIC	C1608 JB 1H 102K-T-A	
C41	4030006930	S.CERAMIC	C1608 CH 1H 020C-T-A	
C42		S.CERAMIC	C1608 JB 1H 102K-T-A	
C43		S.CERAMIC	C1608 CH 1H 100D-T-A	
C44		S.CERAMIC	C1608 CH 1H 120J-T-A	
C45 C46		S.CERAMIC S.CERAMIC	C1608 JB 1H 102K-T-A C1608 JB 1H 102K-T-A	
C46		S.CERAMIC	C1608 CH 1H 220J-T-A	
C48		S.CERAMIC	C1608 CH 1H 180J-T-A	
C49		S.CERAMIC	C1608 CH 1H 180J-T-A	
C50	4030006860	S.CERAMIC	C1608 JB 1H 102K-T-A	
C51		S.CERAMIC	C1608 JB 1H 102K-T-A	
C52		S.CERAMIC	C1608 JB 1H 102K-T-A	
C53		S.CERAMIC	GRM42-6 CH 100D 500PT	
C55 C56	4010005790	S.CERAMIC	HM60SJ YB 102K 500V GRM42-6 CH 180J 500PT	
C56	4010007630	CERAMIC	HM60SJ CH 270J 500V	
C58	4030011020	S.CERAMIC	GRM42-6 CK 010C 500PT	
C59	4030007020	S.CERAMIC	C1608 CH 1H 120J-T-A	
C60	4030011020	S.CERAMIC	GRM42-6 CK 010C 500PT	
C61		S.CERAMIC	C1608 CH 1H 120J-T-A	
C62		S.CERAMIC	GRM42-6 CH 270J 500PT	
C63 C64		S.CERAMIC S.CERAMIC	GRM42-6 CH 270J 500PT GRM42-6 CH 150J 500PT	
C65		S.CERAMIC	C1608 JB 1H 102K-T-A	
C66	4010005540	a state of the second sec	HM60SJ SL 030C 500V	
C67		S.CERAMIC	C1608 CH 1H 220J-T-A	
C69		S.CERAMIC	C1608 JB 1H 102K-T-A	
C70		S.CERAMIC	C1608 CH 1H 050C-T-A	
C72	1.2010.0010.0011	S.CERAMIC	C1608 CH 1H 390J-T-A	
C73 C74		S.CERAMIC S.CERAMIC	C1608 CH 1H 030C-T-A C1608 JB 1H 102K-T-A	
C75		S.CERAMIC	C1608 JB 1H 102K-T-A	
C76		S.CERAMIC	C1608 JB 1H 102K-T-A	
C77	4030006860	S CERAMIC	C1608 JB 1H 102K-T-A	
C78			C1608 JB 1H 102K-T-A	
C79		S.CERAMIC	C1608 CH 1H 060D-T-A	
C80	4030008560		C1608 CH 1H 300J-T-A	
C81 C82		S.CERAMIC S.CERAMIC	C1608 CH 1H 020C-T-A C1608 CH 1H 010C-T-A	
C82		S.CERAMIC	C1608 CH 1H 010C-1-A	
C84		S.CERAMIC	C1608 CH 1H 390J-T-A	
C85	1007120725	S.CERAMIC	C1608 CH 1H 010C-T-A	
C86		S.CERAMIC	C1608 CH 1H 010C-T-A	
C87		S.CERAMIC	C1608 CH 1H 060D-T-A	
C88	100 CH # 6 6 10 F	S.CERAMIC	C1608 CH 1H 390J-T-A	
C89 C90		S.CERAMIC S.CERAMIC	C1608 CH 1H 030C-T-A C1608 CH 1H 070D-T-A	
C91	07.000.00.000	S.CERAMIC	C1608 JB 1H 102K-T-A	
C92		S.CERAMIC	C1608 CH 1H 101J-T-A	
C93	4030006860	S.CERAMIC	C1608 JB 1H 102K-T-A	
C94		S.CERAMIC	C1608 JB 1H 102K-T-A	
C95	12222000000000	S.CERAMIC	C1608 CH 1H 050C-T-A	
C96 C97	10223020000000000000	S.CERAMIC	C1608 JB 1H 102K-T-A C1608 JB 1H 102K-T-A	
C97		S.CERAMIC S.CERAMIC	C1608 JB 1H 102K-1-A C1608 CH 1H 820J-T-A	
C100		S.CERAMIC	C1608 JB 1H 102K-T-A	
C101		S.CERAMIC	C1608 JB 1H 102K-T-A	
C102		S.CERAMIC	C2012 JF 1C 105Z-T-A	
C103	4030006860		C1608 JB 1H 102K-T-A	
C105		S.TANTALUM	TESVA 1V 104M1-8L	
C106	0.0000000000000000000000000000000000000	S.CERAMIC	C1608 JB 1H 102K-T-A	
C107 C108		S.TANTALUM S.TANTALUM	TESVA 1V 104M1-8L TESVA 1A 225M1-8L	
C109		S.CERAMIC	C1608 JB 1E 103K-T-A	
C111	1 P C C C A S C Y C C	S.CERAMIC	C1608 CH 1H 120J-T-A	
C112		S.CERAMIC	C1608 CH 1H 120J-T-A	
	1020006030	S.CERAMIC	C1608 CH 1H 020C-T-A	
C113 C114		S.CERAMIC	C1608 CH 1H 050C-T-A	

[MAIN UNIT]

REF NO.	ORDER NO.	D	ESCRIPTION
C116		S.CERAMIC	GRM40 RH 330J 50PT
C117		S.CERAMIC	GRM40 RH 220J 50PT
C118	4030001810	S.CERAMIC	GRM40 RH 180J 50PT
C119		S.TRIMMER	CTZ3S-30C-W1-AF
C121		S.CERAMIC	C1608 JB 1H 102K-T-A
C128 C129	4030006860	S.CERAMIC S.CERAMIC	C1608 JB 1H 102K-T-A C1608 JF 1C 104Z-T-A
C129			C2012 JB 1E 473K-T-A
C131			C1608 JB 1C 223K-T-A
C132	4030007130	SCERAMIC	C1608 CH 1H 101J-T-A
C133	4030006860	S.CERAMIC S.CERAMIC	C1608 JB 1H 102K-T-A
C134			C2012 JF 1C 105Z-T-A
C135	4030006860	S.CERAMIC	C1608 JB 1H 102K-T-A
C136 C137	4030008680	S.CERAMIC S.CERAMIC	C2012 JF 1C 105Z-T-A C1608 CH 1H 300J-T-A
C139	4030007170	S.CERAMIC	C1608 CH 1H 221J-T-A
C140	4030007170	S.CERAMIC	C1608 CH 1H 221J-T-A
C141	4030006850	S.CERAMIC	C1608 JB 1H 471K-T-A
C142		S.CERAMIC	C1608 JF 1C 104Z-T-A
C143	4030006900	S.CERAMIC	C1608 JB 1E 103K-T-A
C144 C145	4030008860	S.CERAMIC S.CERAMIC	C1608 JB 1C 153K-T-A C1608 JB 1H 102K-T-A
C145		S.CERAMIC	C1608 JB 1C 333K-T-A
C147		S.CERAMIC	C1608 JB 1C 153K-T-A
C148		S CERAMIC	C1608 JB 1H 562K-T-A
C149	4030008770	S.CERAMIC	C1608 JB 1H 562K-T-A
C150			C2012 JF 1C 105Z-T-A
C151 C152	4030008630	S.CERAMIC S.CERAMIC	C1608 JF 1C 104Z-T-A C1608 JB 1H 102K-T-A
C152 C153	4030000000	S.CERAMIC	C1608 JB 1E 103K-T-A
C154	4030006860	S.CERAMIC	C1608 JB 1H 102K-T-A
C155	4030006860	S.CERAMIC	C1608 JB 1H 102K-T-A
C156			C1608 JB 1H 102K-T-A
C157			C1608 JB 1H 102K-T-A
C158	4510006020 4030006860	ELECTROLYTIC	16 MV 2200 HC C1608 JB 1H 102K-T-A
C159 C160			C1608 JB 1H 102K-T-A
C161		S.CERAMIC	C1608 JB 1H 102K-T-A
C162	the second second		C1608 JB 1H 102K-T-A
C163	0000666666666	S.ELECTROLYTIC	A COMPANY AND A CO
C164	4030006860	Contraction of the second s	C1608 JB 1H 102K-T-A
C165		S.CERAMIC S.ELECTROLYTIC	C1608 JB 1H 102K-T-A ECEV1CA470SP
C166 C167		S.ELECTROLYTIC	ECEVICA470SP ECEVICA100SR
C168		S.CERAMIC	C1608 JB 1H 102K-T-A
C169	4510006220	S.ELECTROLYTIC	ECEV1CA101UP
C170		S.CERAMIC	C1608 JB 1H 102K-T-A
C171		S.ELECTROLYTIC	
C172		and the second se	ECEV1HA010SR C1608 JB 1H 102K-T-A
C173 C174	4030006860	S.ELECTROLYTIC	ECEV0JA470SR
C175		S.ELECTROLYTIC	ECEV1HA010SR
C176	4550006130	S.TANTALUM	ECST1VY224R
C177		S.ELECTROLYTIC	ECEV1CA470SP
C178		S.ELECTROLYTIC	ECEV1AA471UP
C179 C180		S.CERAMIC S.CERAMIC	C1608 JB 1H 102K-T-A C1608 JB 1H 102K-T-A
C181	The second se	S.ELECTROLYTIC	ECEV1CA470SP
C182		S.ELECTROLYTIC	ECEV1CA100SR
C183	4030006860	and the same has been dealed and the same set of the same set	C1608 JB 1H 102K-T-A
C184		S.CERAMIC	C1608 JB 1H 102K-T-A
C185 C186	4030006860	S.CERAMIC	C1608 JB 1H 102K-T-A C1608 JB 1H 102K-T-A
C180	. 바람이 아이에 가지 않는 것이다.	S.CERAMIC	C1608 JB 1H 102K-T-A
C188	4030006860		C1608 JB 1H 102K-T-A
C189		S.CERAMIC	C1608 JB 1H 102K-T-A
C190	4030006860	S.CERAMIC	C1608 JB 1H 102K-T-A
C191	4030006860		C1608 JB 1H 102K-T-A C1608 JB 1H 102K-T-A
C192 C193	4030006860	S.CERAMIC S.CERAMIC	C1608 JB 1H 102K-T-A
C194		S.CERAMIC	C1608 JB 1H 102K-T-A
C195	4030006860	S.CERAMIC	C1608 JB 1H 102K-T-A
C196	4030006860	S.CERAMIC	C1608 JB 1H 102K-T-A
C197	4510005870	S.ELECTROLYTIC	ECEV1HA3R3SR
C198 C199	4030006860 4030006860	S.CERAMIC	C1608 JB 1H 102K-T-A C1608 JB 1H 102K-T-A
C200		S.ELECTROLYTIC	ECEVICA100SR
C201	4510004630	S.ELECTROLYTIC	ECEV1CA100SR
C202	4510004630	S.ELECTROLYTIC	ECEV1CA100SR
C203	4030006860	S.CERAMIC	C1608 JB 1H 102K-T-A
C204 C205	4030006860 4030008630	S.CERAMIC S.CERAMIC	C1608 JB 1H 102K-T-A C1608 JF 1C 104Z-T-A
0200	-1030008630	S.OLIMINIC	0100001 10 1042-1-A

[MAIN UNIT]

4030008750 4030006890 4030007000 4030006850 4030006850 4030006850 4030006850 4030006850 4030006630 4030006630 4030006630 4030006860 4030006860	S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC	C1608 JB 1H 102K-T-A C1608 JB 1H 102K-T-A
4030008750 4030006890 4030007000 4030006850 4030006850 4030006850 4030006850 4030006850 4030006630 4030006630 4030006630 4030006860 4030006860	S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC	C1608 CH 1H 360J-T-A C1608 CH 1H 080D-T-A C1608 CH 1H 090D-T-A C1608 JB 1H 102K-T-A C1608 JF 1C 1042-T-A C1608 JB 1H 102K-T-A [EUR], [ITA] on ECEV1CA100SR C1608 JB 1H 102K-T-A C1608 JB 1H 102K-T-A
4030006990 4030005800 403000570 4030006850 4030006850 4030006860 4030006860 4030008630 4030008630 4030006860 4030006860 4030006860 4030006860	S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC	C1608 CH 1H 080D-T-A C1608 CH 1H 090D-T-A C1608 JB 1H 102K-T-A C1608 JB 1H 102K-T-A C1608 JB 1H 471K-T-A C1608 JB 1H 471K-T-A C1608 JB 1H 102K-T-A C1608 JB 1H 102K-T-A C1608 JF 1C 1042-T-A C1608 JF 1C 1042-T-A C1608 JF 1C 1042-T-A C1608 JF 1C 1042-T-A C1608 JB 1H 102K-T-A ECEV1CA100SR C1608 JB 1H 102K-T-A C1608 JB 1H 102K-T-A
4030007000 4030006860 4030006850 4030006850 4030006860 4030006860 4030008630 4030008630 4030006860 4030006860 4030006860 4030006860	S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.ELECTROLYTIC S.CERAMIC S.CERAMIC	C1608 CH 1H 090D-T-A C1608 JB 1H 102K-T-A C1608 JB 1H 102K-T-A C1608 JB 1H 471K-T-A C1608 JB 1E 103K-T-A C1608 JB 1H 102K-T-A C1608 JB 1H 102K-T-A C1608 JF 1C 104Z-T-A C1608 JF 1C 104Z-T-A C1608 JF 1C 104Z-T-A C1608 JF 1C 104Z-T-A C1608 JB 1H 102K-T-A ECEV1CA100SR C1608 JB 1H 102K-T-A
4030006860 4030009570 4030006850 4030006800 4030006860 4030006860 4030006860 4030006860 4030006860 4030006860 4030006860	S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.ELECTROLYTIC S.CERAMIC S.CERAMIC	C1608 JB 1H 102K-T-A C1608 CH 1H 0R3B-T-A C1608 JB 1H 471K-T-A C1608 JB 1E 103K-T-A C1608 JB 1H 102K-T-A C1608 JB 1H 102K-T-A C1608 JF 1C 104Z-T-A C1608 JF 1C 104Z-T-A C1608 JF 1C 104Z-T-A C1608 JB 1H 102K-T-A EUR], [ITA] on ECEV1CA100SH C1608 JB 1H 102K-T-A C1608 JB 1H 102K-T-A
4030009570 4030006850 4030006860 4030006860 4030006860 4030006860 4030006860 4030006860 4030006860 4030006860 4030006860	S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.ELECTROLYTIC S.CERAMIC S.CERAMIC	C1608 CH 1H 0R3B-T-A C1608 JB 1H 471K-T-A C1608 JB 1E 103K-T-A C1608 JB 1H 102K-T-A C1608 JB 1H 102K-T-A C1608 JF 1C 104Z-T-A C1608 JF 1C 104Z-T-A C1608 JF 1C 104Z-T-A C1608 JB 1H 102K-T-A IEUR], [ITA] on ECEV1CA100SR C1608 JB 1H 102K-T-A
4030006850 4030006800 4030006800 4030006800 4030008630 4030006830 4030006860 4510004630 4030006860 4030006860	S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.ELECTROLYTIC S.CERAMIC S.CERAMIC	C1608 JB 1H 471K-T-A C1608 JB 1E 103K-T-A C1608 JB 1H 102K-T-A C1608 JB 1H 102K-T-A C1608 JF 1C 104Z-T-A C1608 JF 1C 104Z-T-A C1608 JB 1H 102K-T-A [EUR], [ITA] on ECEV1CA100SR C1608 JB 1H 102K-T-A C1608 JB 1H 102K-T-A
4030006900 4030006860 4030008630 4030008630 4030006630 4030006860 4030006860 4030006860 4030006860	S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.ELECTROLYTIC S.CERAMIC S.CERAMIC	C1608 JB 1E 103K-T-A C1608 JB 1H 102K-T-A C1608 JB 1H 102K-T-A C1608 JF 1C 104Z-T-A C1608 JF 1C 104Z-T-A C1608 JB 1H 102K-T-A [EUR], [ITA] on ECEV1CA100SR C1608 JB 1H 102K-T-A C1608 JB 1H 102K-T-A
4030006860 4030008630 4030008630 4030006860 4510004630 4030006860 4030006860 4030006860	S.CERAMIC S.CERAMIC S.CERAMIC S.CERAMIC S.ELECTROLYTIC S.CERAMIC S.CERAMIC	C1608 JB 1H 102K-T-A C1608 JB 1H 102K-T-A C1608 JF 1C 1042-T-A C1608 JF 1C 1042-T-A C1608 JB 1H 102K-T-A [EUR], [ITA] on ECEV1CA100SR C1608 JB 1H 102K-T-A C1608 JB 1H 102K-T-A
4030008630 4030008630 4030006860 4510004630 4030006860 4030006860 4030006860	S.CERAMIC S.CERAMIC S.CERAMIC S.ELECTROLYTIC S.CERAMIC S.CERAMIC	C1608 JB 1H 102K-T-A C1608 JF 1C 104Z-T-A C1608 JF 1C 104Z-T-A C1608 JB 1H 102K-T-A [EUR], [ITA] on ECEV1CA100SR C1608 JB 1H 102K-T-A C1608 JB 1H 102K-T-A
4030008630 4030008630 4030006860 4510004630 4030006860 4030006860 4030006860	S.CERAMIC S.CERAMIC S.CERAMIC S.ELECTROLYTIC S.CERAMIC S.CERAMIC	C1608 JF 1C 104Z-T-A C1608 JF 1C 104Z-T-A C1608 JB 1H 102K-T-A [EUR], [ITA] on ECEV1CA100SR C1608 JB 1H 102K-T-A C1608 JB 1H 102K-T-A
4030008630 4030006860 4510004630 4030006860 4030006860 4030006860	S.CERAMIC S.CERAMIC S.ELECTROLYTIC S.CERAMIC S.CERAMIC	C1608 JF 1C 104Z-T-A C1608 JB 1H 102K-T-A [EUR], [ITA] on ECEV1CA100SR C1608 JB 1H 102K-T-A C1608 JB 1H 102K-T-A
4510004630 4030006860 4030006860 4030006860	S.ELECTROLYTIC S.CERAMIC S.CERAMIC	[EUR], [ITA] on ECEV1CA100SR C1608 JB 1H 102K-T-A C1608 JB 1H 102K-T-A
4030006860 4030006860 4030006860	S.CERAMIC S.CERAMIC	C1608 JB 1H 102K-T-A C1608 JB 1H 102K-T-A
4030006860 4030006860	S.CERAMIC	C1608 JB 1H 102K-T-A
4030006860	and the second	A DESCRIPTION OF A DESC
	S.CERAMIC	
4030008630		C1608 JB 1H 102K-T-A [EUR], [ITA] on
	S.CERAMIC	C1608 JF 1C 104Z-T-A [EUR], [ITA] on
		ECEV0JA470SR
	S.CERAMIC	C1608 CH 1H 010C-T-A
		ECEV1HA2R2SR
4030011600	S.CERAMIC	C1608 JB 1C 104KT-N
P. C. S. C. C. S. S. S. C. S.		C1608 JB 1H 102K-T-A
	15755 BC COL 16	C1608 JB 1H 102K-T-A
		C1608 JB 1H 102K-T-A
		C1608 JB 1H 102K-T-A
A C C C C A A A A A A A	124 224 C (2000 C)	and the second sec
		C1608 JB 1H 102K-T-A
	Care and the second second second	C1608 JB 1H 102K-T-A
100000000000	Certain and a state of the	C1608 JB 1H 102K-T-A
		C1608 JB 1H 102K-T-A
		C1608 JB 1H 102K-T-A
Provide a contract of		C1608 JB 1H 102K-T-A
Contraction of the second second	S.CERAMIC	C1608 JB 1H 102K-T-A
4030006860	S.CERAMIC	C1608 JB 1H 102K-T-A
4030008680	S.CERAMIC	C2012 JF 1C 105Z-T-A
6510018040 6450001900	CONNECTOR	52330-1217 52330-1217 HSJ0912-01-020 B2B-ZR-SM3-TF
		OPC-465
		ERJ3GE JPW V
		ERDS2T0
7030003860	S.JUMPER	ERJ3GE JPW V
7030003860	S.JUMPER	except [EUR], [ITA ERJ3GE JPW V
7030003860	S.JUMPER	except [EUR], [ITA ERJ3GE JPW V
		ERJ3GE JPW V
7030003860	S.JUMPER	ERJ3GE JPW V ERJ3GE JPW V
0910049552	PCB	B 5098B
		0.7(d) L=14 mm
	4030011600 4030006860 4030006860 4030006860 4030006860 4030006860 4030006860 4030006860 4030006860 4030006860 4030006860 4030006860 4030006860 4030006860 4030006860 4030006860 4030006860 7030003860 7030003860 7030003860 7030003860 7030003860 7030003860 7030003860 7030003860 7030003860	4030006860 S.CERAMIC 510018040 CONNECTOR 5510014960 CONNECTOR 510013040 CONNECTOR 7030003860 S.JUMPER 7030003860

SECTION 6 MECHANICAL PARTS AND DISASSEMBLY

[CHASSIS PARTS]

REF. NO.	ORDER NO.	DESCRIPTION	QTY
J1	6510004880	Antena connector MR-DSE-01	1
SP1	2510000820	Speaker VS-57-0814	1
MP1	8010017280	2088 chassis	1
MP2	8110006430	2088 cover (include felt, speaker net)	1
MP4	8930045600	2088 SP rubber	1
MP5	8810008660	Screw PH BO M3x8 NI-ZU (BT)	2
MP6	8810008660	Screw PH BO M3x8 NI-ZU (BT)	7
MP7	8810009610	Screw FH M2.6x6 ZK	4
MP8	8810005160	Hex socket bolt M3x20 ZK	2
MP9	8810008660	Screw PH BO M3x8 NI-ZU (BT)	2
MP10	8810008660	Screw PH BO M3x8 NI-ZU (BT)	1
MP15	8930039610	Thermally sheet (C)	3
MP16	8930041160	Thermally sheet (G)	1

[LOGIC UNIT]

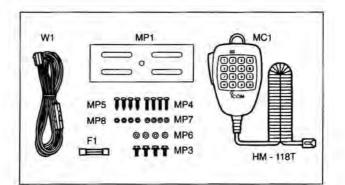
REF. NO.	ORDER NO.	DESCRIPTION	QTY.
R61	7210001870	Variable resistor EVU-F2AF20A14 [VOL]	1
R62	7210001860	Variable resistor EVU-F2AF20B14 [SQL]	1
DS1	5030001570	LCD LD-HU10238E	1
S9	2250000370	Encoder EVQ-VENF01 24B	1
EP2	8930045730	LCD contact SRCN-2088-SP-N-W	1
MP1	8210015290	2088 Reflector	140
MP2	8930045610	2088 LCD filter	1
MP3	8210015381	2088 Front panel (A)-1 [THA] only	1
1.000	8210015281	2088 Front panel-1 other	1
MP4	8510011580	2088 Front plate	1
MP5	8930045580	2088 2-button	1
MP6	8930045590	2088 6-button	1
MP7	8610010610	Knob N-266	1
MP8	8610010601	Knob N-267-1	2
MP10	8810008760	Screw PH BO M2x8 NI-ZU (BT)	4
MP11	8930047310	Sponge (FW)	1

[MIAN UNIT]

REF. NO.	ORDER NO.	DESCRIPTION	QTY.
W1	8900004880	Cable OPC-465	1
MP1	8510011660	2088 VCO case	1

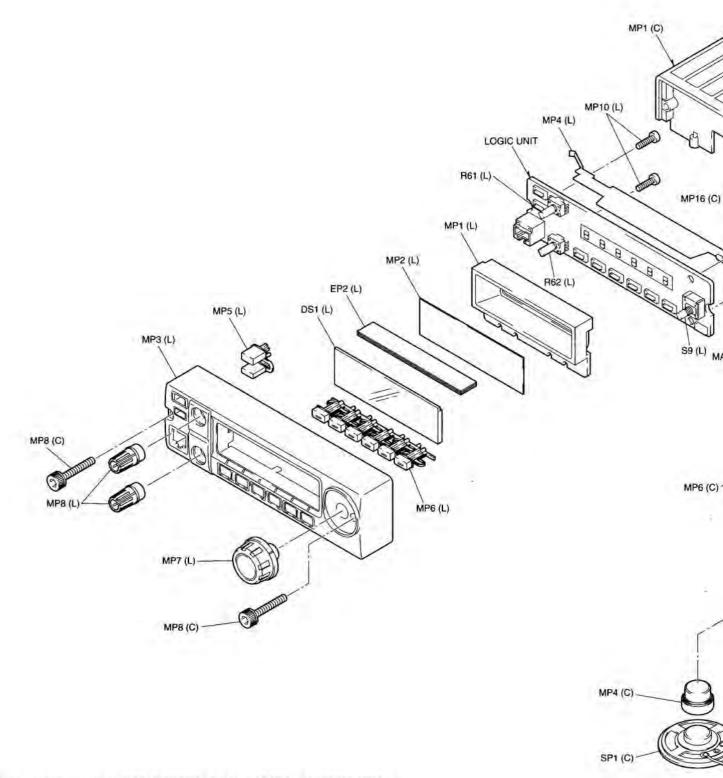
[ACCESSORIES]

REF. NO.	ORDER NO.	DESCRIPTION	QTY
F1	5210000080	Fuse (20A)	1
MC1	Optional product	Microphon HM-97 [EUR], [ITA]	1
	Optional product	Microphon HM-98S [TPE], [USA]	1
	Optional product	Microphon HM-118 [SEA]	1
	Optional product	Microphon HM-118T [THA], [LA]	1
W1	8900003760	Cable OPC-346	1
MP1	8010016380	1542 Mobil bracket (B)	1
MP3	8820000530	Flange bolt M4x8	4
MP4	8810000470	Screw PH M5x12 (+/-)	4
MP5	8810000950	Screw PH A0 M5x16	4
MP7	8850000150	Flat washer M5 NI BS	4
MP8	8830000120	Nut M5	4

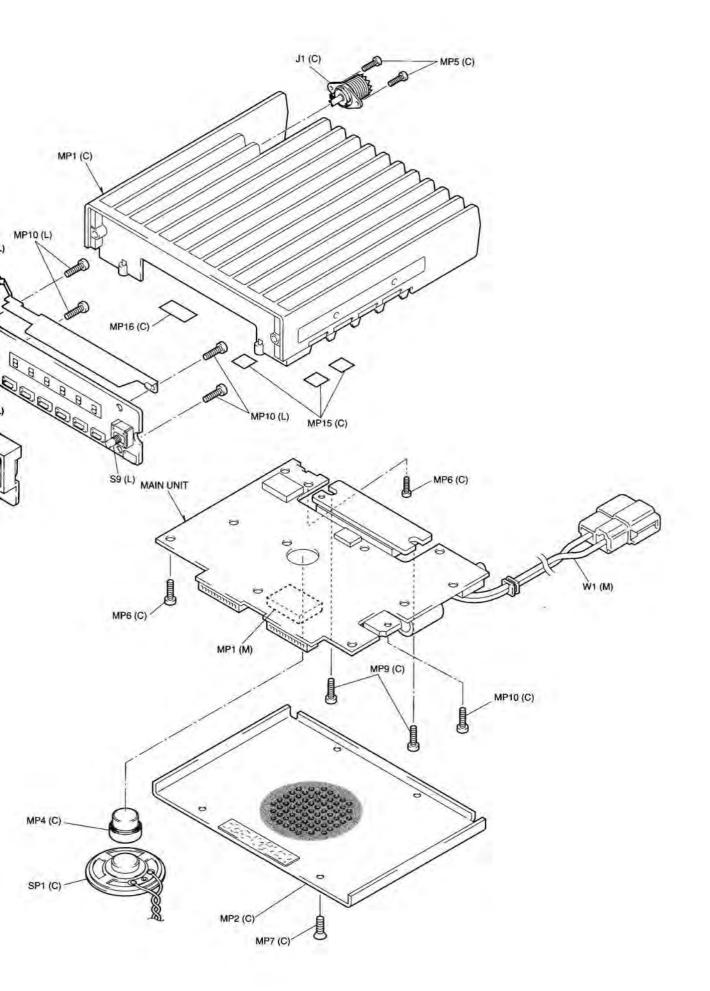


Screw abbreviations

A, B0, BT: Self-tapping PH: Pan head FH: Flat head BiH: Bind head NI: Nickel SUS: Stainless ZK: Black

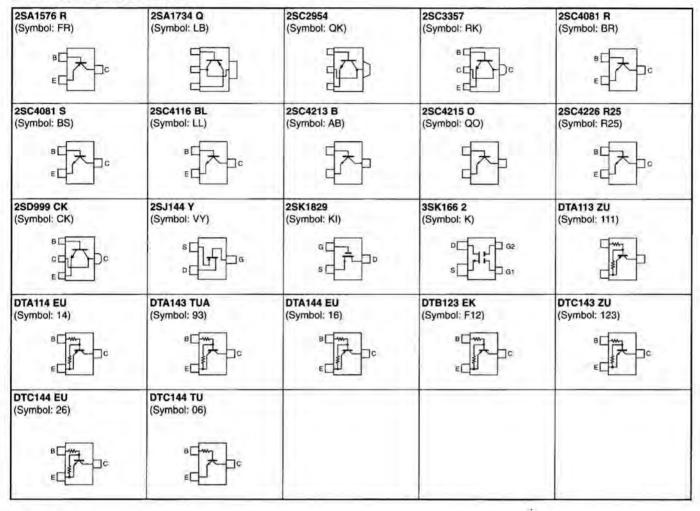


UNIT abbreviation (C): CHASSIS PARTS, (L): LOGIC UNIT, (M): MAIN UNIT



SECTION 7 SEMI-CONDUCTOR INFORMATION

TRANSISTOR AND FET'S



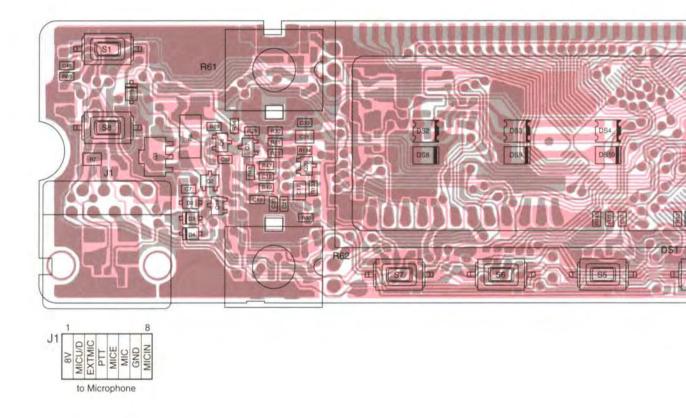
DIODES

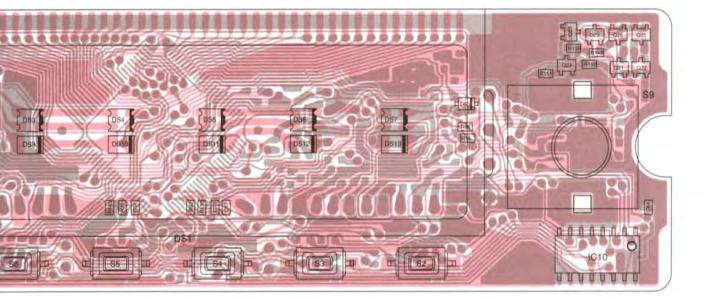
S355	DA114	DA115	DA204U	DA221
mbol: A)	(Symbol: AV)	(Symbol: AU)	(Symbol: K)	(Symbol: K)
N202 U	HVU350	MA742	MA862	MA8047 M
mbol: N)	(Symbol: 4)	(Symbol: M1U)	(Symbol: M1I)	(Symbol: 4-7)
8091 M mbol: 9-1)				

SECTION 8 BOARD LAYOUTS

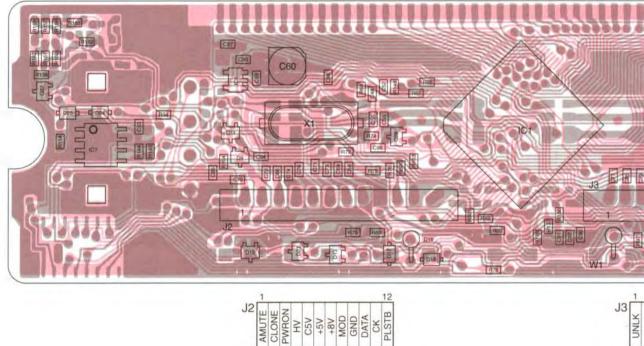
8-1 LOGIC UNIT

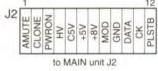
TOP VIEW

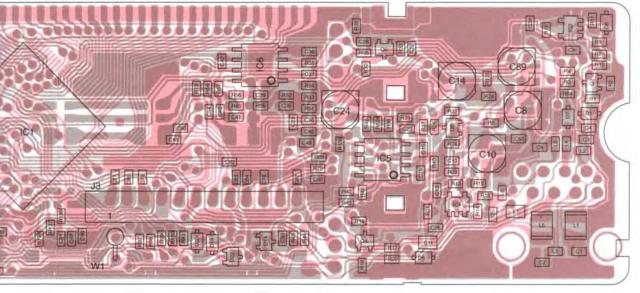




BOTTOM VIEW



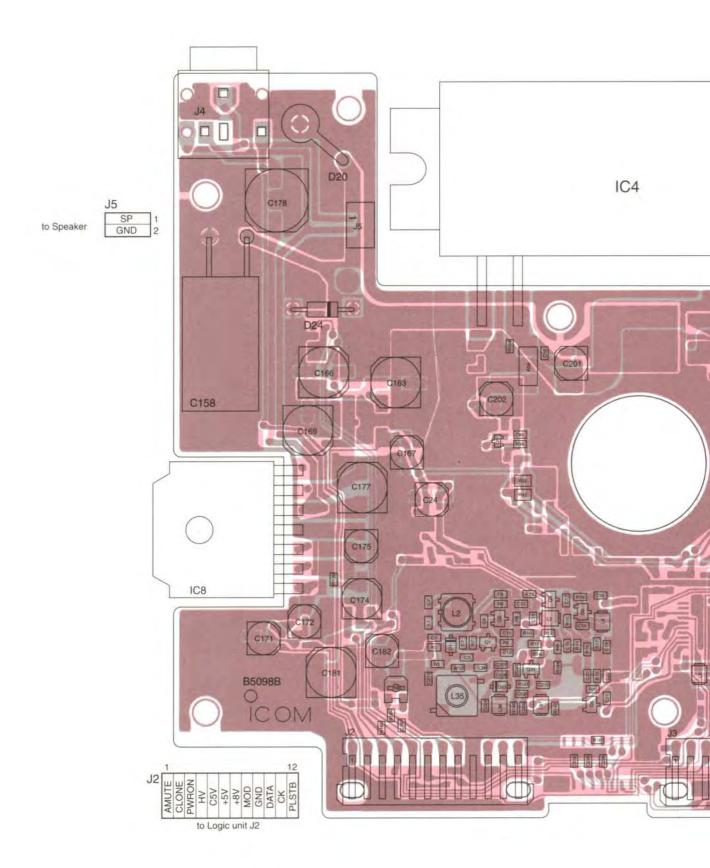


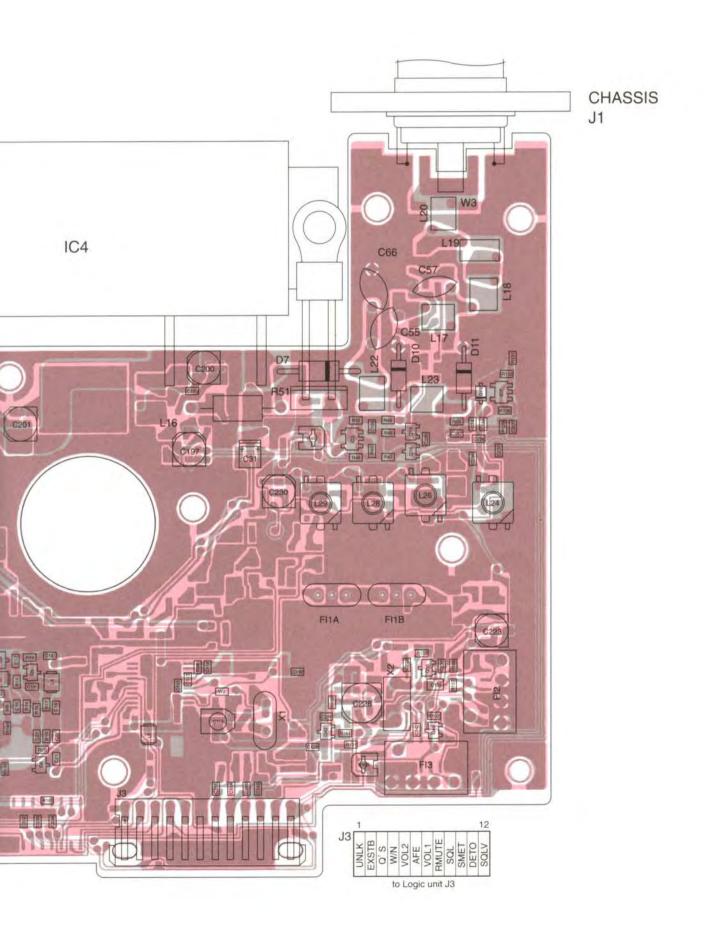


12 1 J3 UNLK EXSTB Q'S W/N VOL2 AFE VOL1 RMUTE SQL SMET DETO SQLV to MAIN unit J3

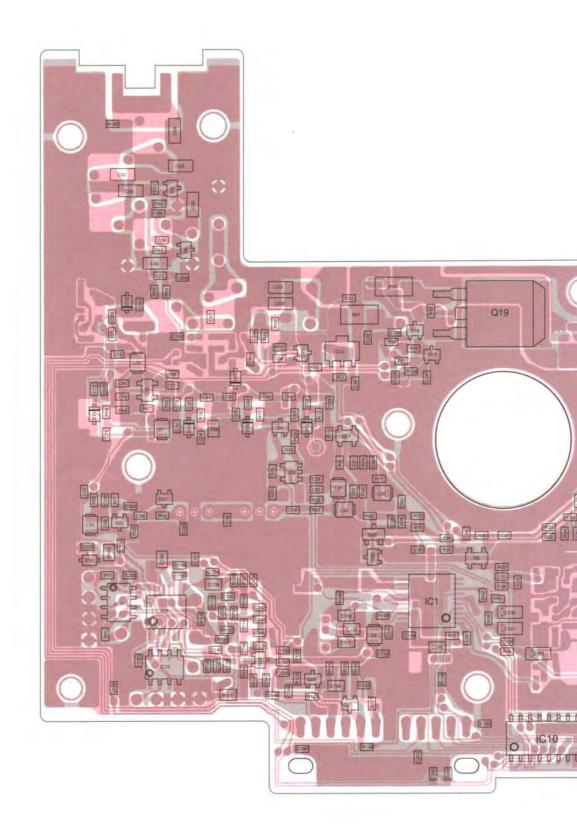
8-2 MIAN UNIT

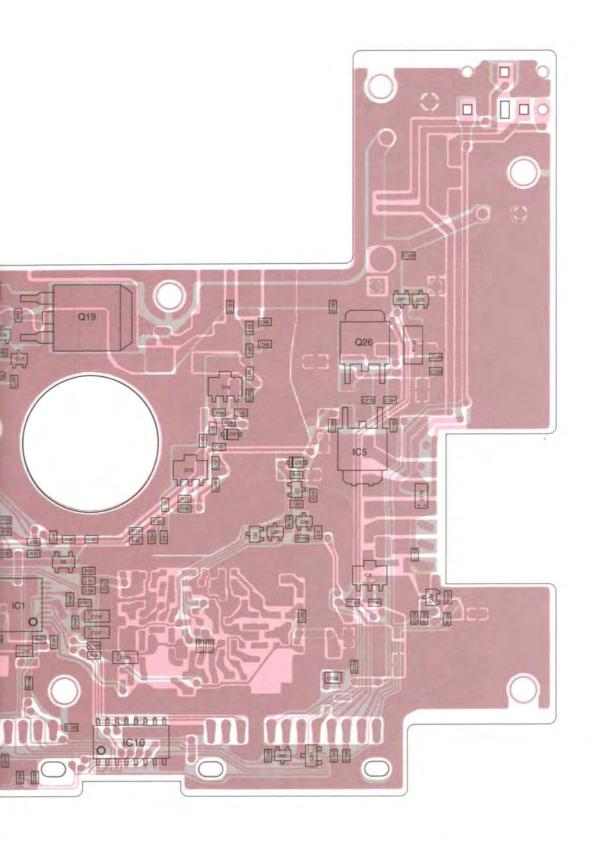
TOP VIEW



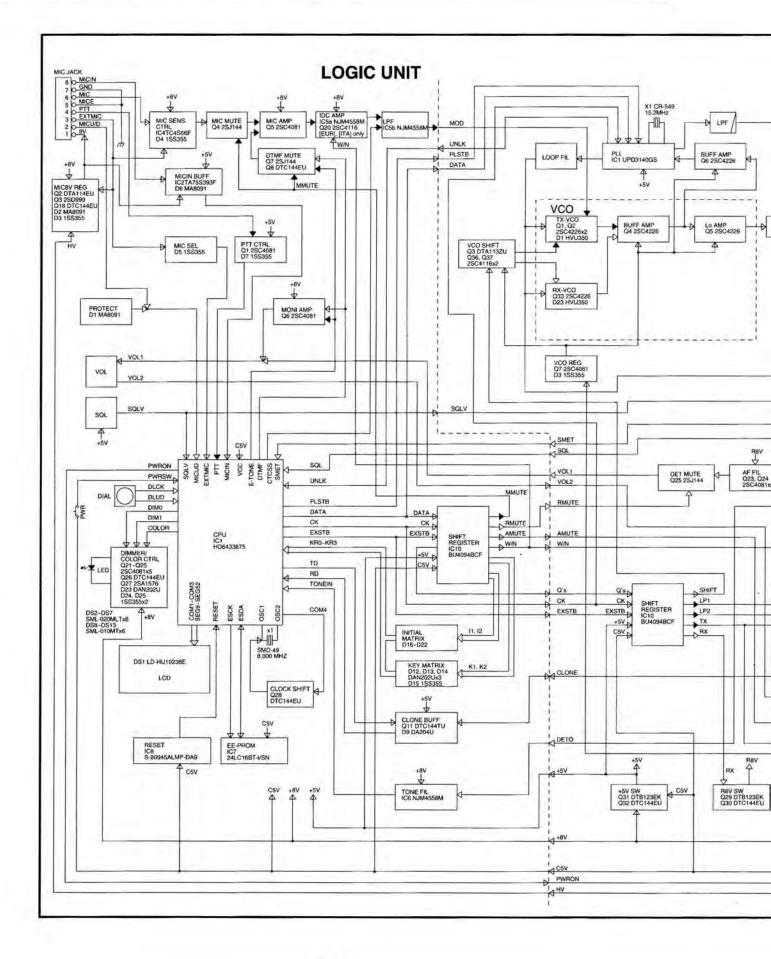


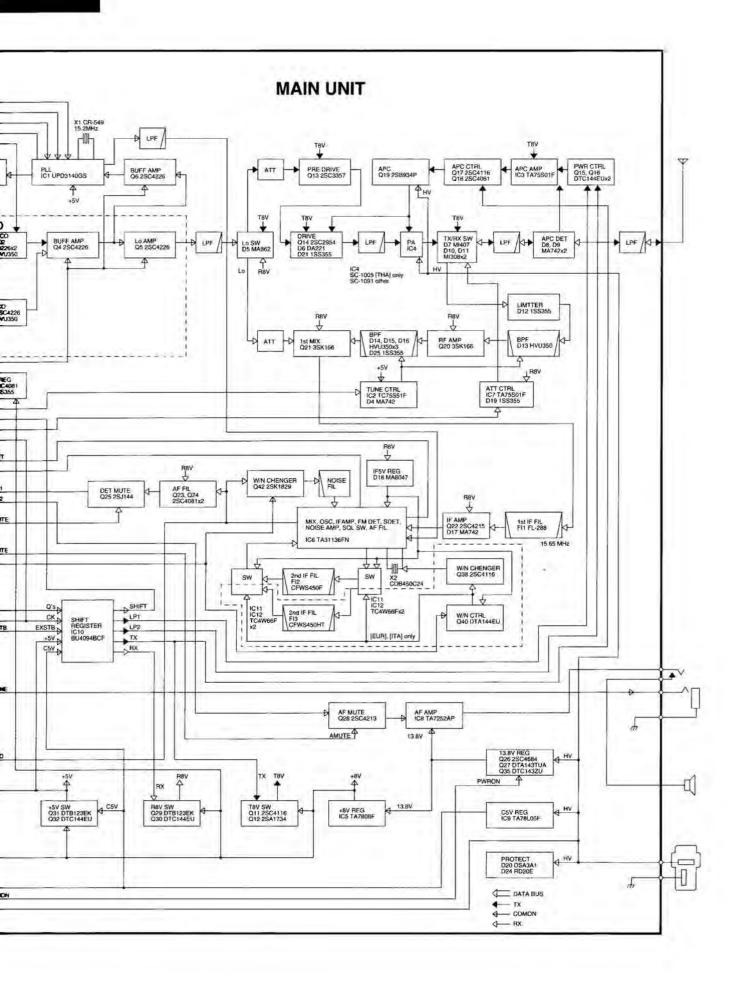
BOTTOM VIEW





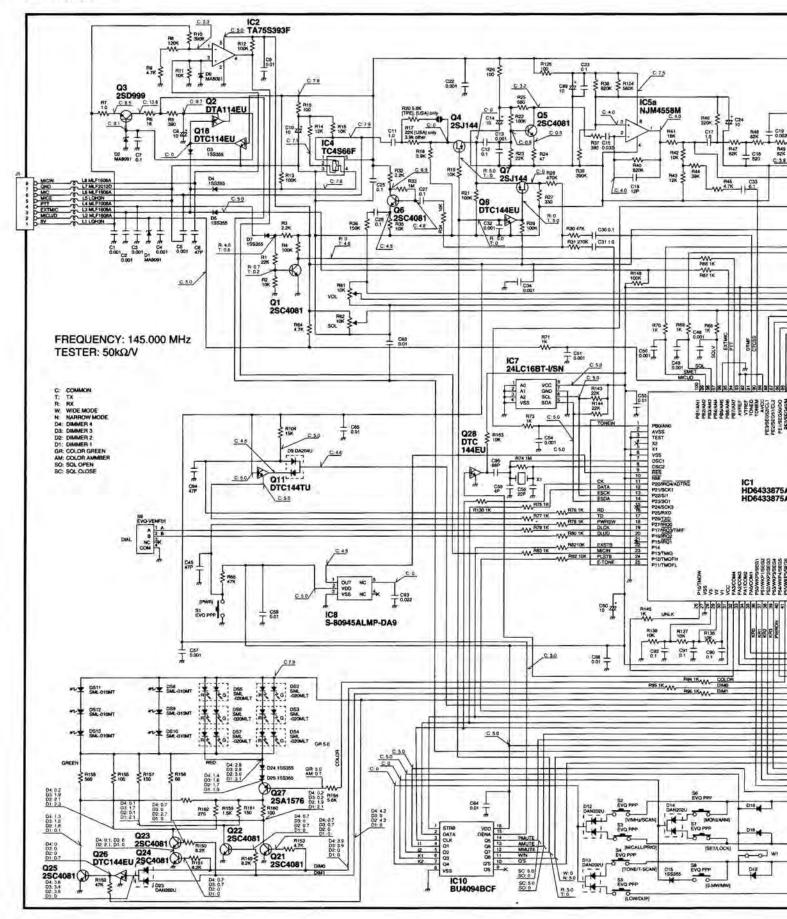
SECTION 9 BLOCK DIAGRAM

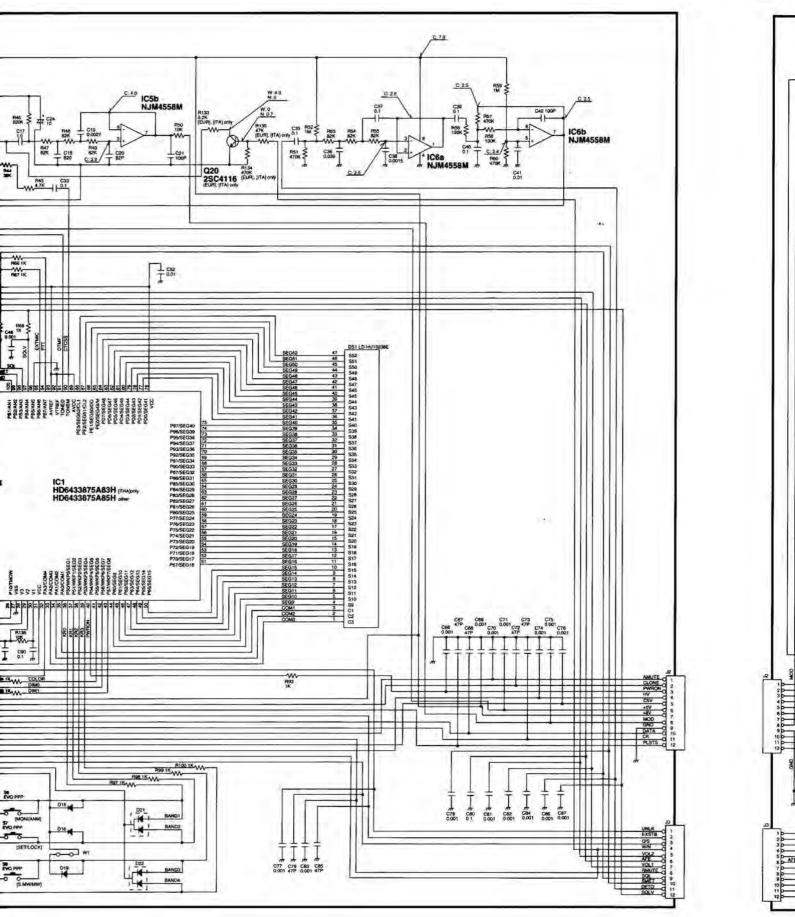




SECTION 10 VOLTAGE DIAGRAM

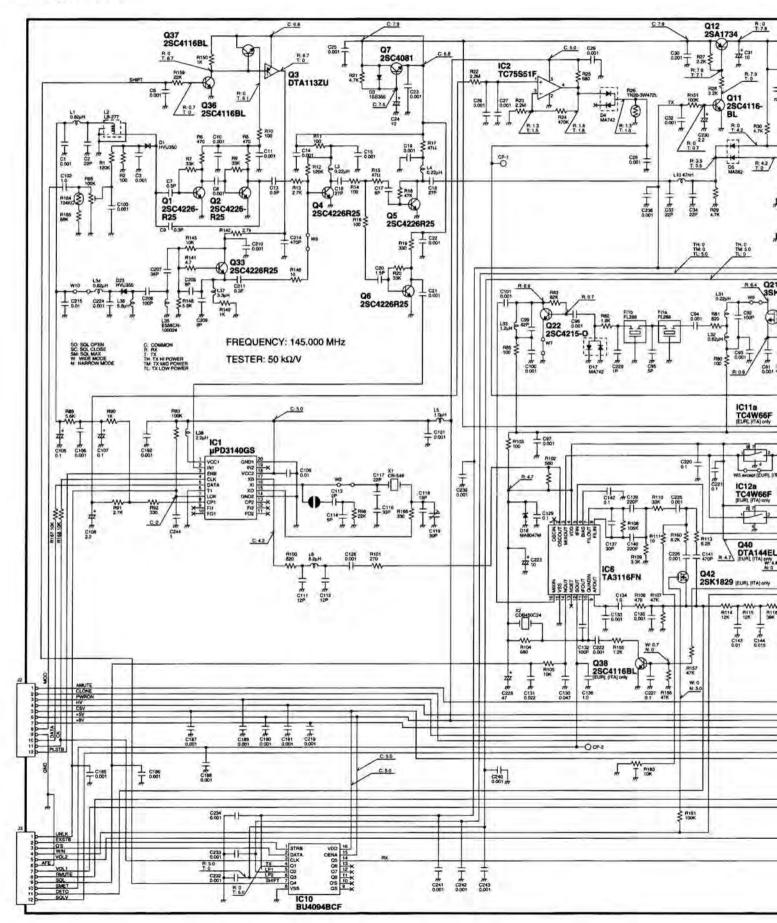
LOGIC UNIT

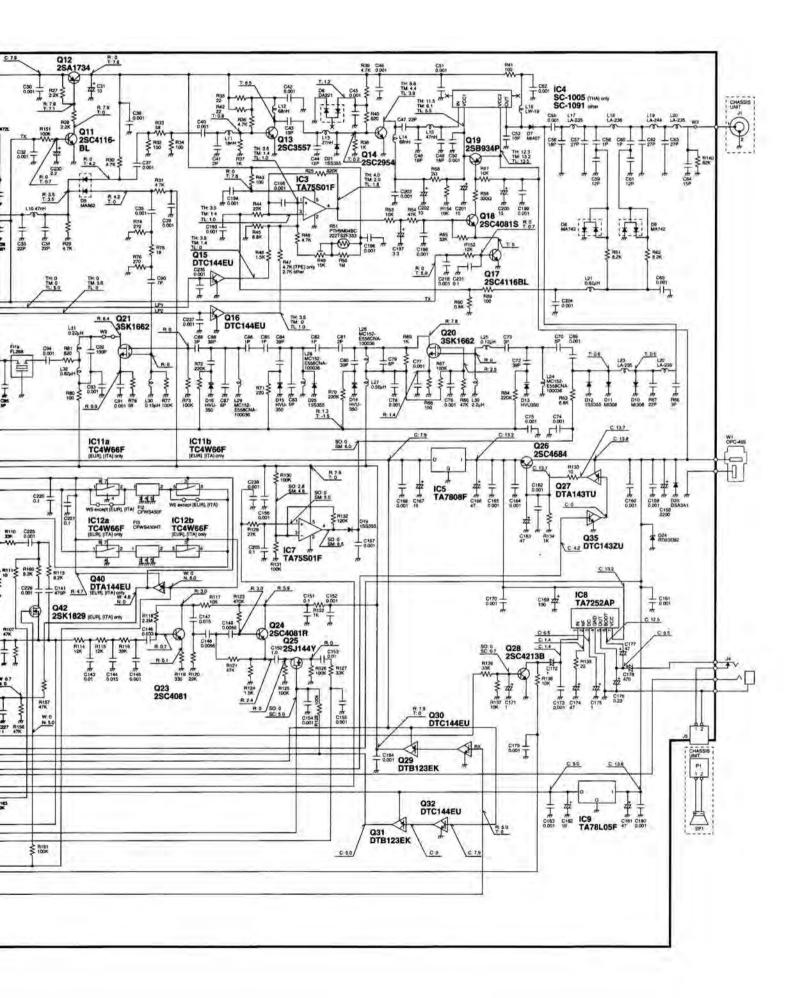




• N

MAIN UNIT





Icom Inc.

6-9-16, Kamihigashi, Hirano-ku, Osaka 547-0002, Japan Phone : 06 793 5302 Fax : 06 793 0013

Icom America Inc.

Corporate Headquarters> 2580 116th Avenue N.E., Bellevue, WA 98004, U.S.A. Phone: (425) 454-8155 Fax. (425) 454-1509 URL : http://www.icomamerica.com

<Customer Service> Phone (425) 454-7619

Icom Canada

A Division of Icom America Inc. 3071 #5 Road, Unil 9, Richmond, B.C., V6X 2T4, Canada Phone: (604) 273-7400 Fax: (604) 273-1900

Icom (Australia) Pty. Ltd. A.C.N. 006 092 575 290-294 Albert Street, Brunswick, Victoria, 3056, Australia Phone: 03 9387 0666 Fax, 03 9387 0022

Asia Icom Inc.

6F No. 68. Sec. 1 Chang-Ten Road, Taiper, Taiwan R.O.C.

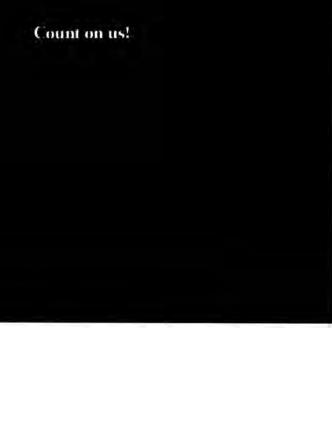
Icom (Europe) GmbH

Communication Equipment Himmetgeister Str. 100, D-40225 Düsseldort, Germany Phone: 0211 346047 Fax: 02211 333639 URL: http://www.icomeurope.com Icom Telecomunicaciones s.l.

"Edificio Can Castanyer" Cita. Gracia a Manresa km. 14,750 08190 Sant Cugat Del Valles Barcelona, SPAIN Phone: (3) 589 46 82 - Fax: (3) 589 04 46 E-mail: icom@lleida.com

Icom (UK) Ltd.

Unit 9, Sea SL, Herne Bay, Kenl, CT6 8LD, U.K. Phone: 01227 741741 Fax: 01227 741742 URL: http://www.icomuk.co.uk Icom France S.a Zac de ta Plaine, Rue Brindejonc des Moulinais BP 5804, 31505 Toulouse Cedex, France Phone: 561 36 03 03 Fax: 561 36 03 00 URL: http://www.icom-france.com



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